

phellia

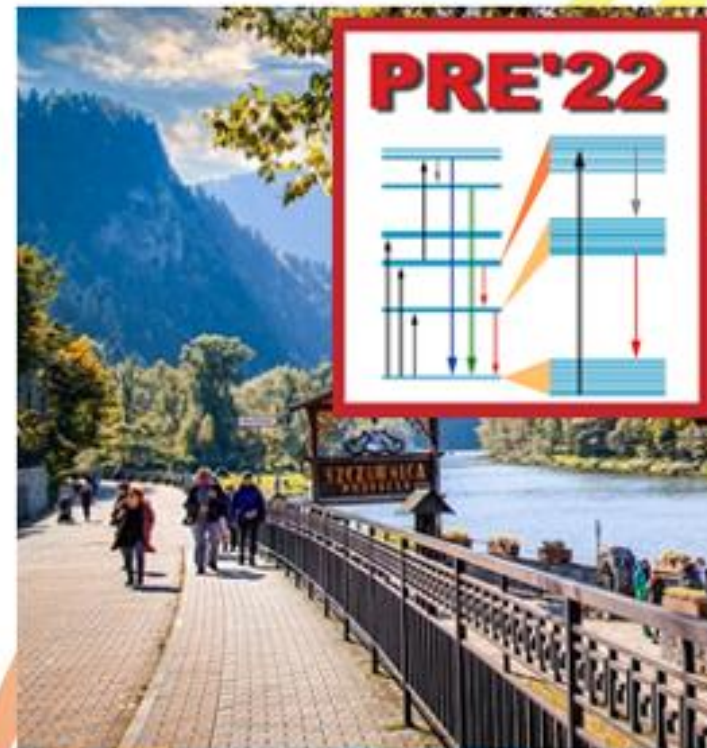
ON-CHIP PHOTONICS ERBIUM-DOPED LASER FOR LIDAR APPLICATIONS



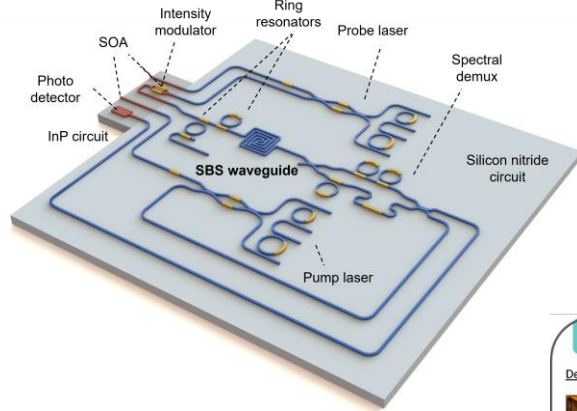
ICMS 2022

Szczawnica, 11-14.09.2022

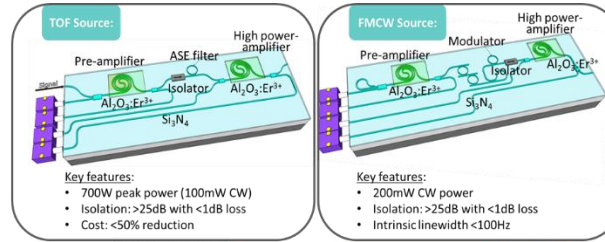
PRE'22-Poland



At the UT we carry out research in Integrated Photonics covering materials, devices and systems for different applications, including RF photonics, LiDAR, sensing and quantum technology



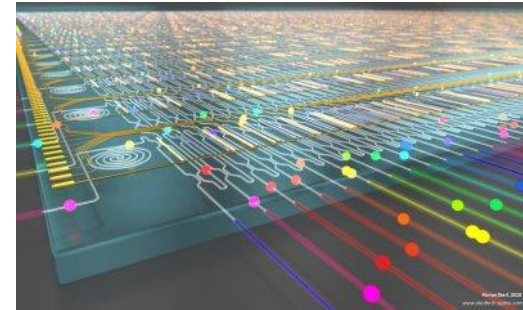
Brillouin gain in Si_3N_4



PIC/packaging partners: UNIVERSITY OF TWENTE, Lionix INTERNATIONAL, KEOPSYS INDUSTRIES, Vanguard AUTOMATION



Building blocks:
 • Pre-amplifier
 • High power amplifier
 • Isolator



Quantum processing

Demonstrators:

Demo1: **SICK**
Sensor Intelligence.

- Safety in harbors and airports
- Industry 4.0

Demo2: **RIEGL**

- Autonomous robots/drones
- Industrial environments

Demo3: **THALES**

- Autonomous trains
- Safety

Other application fields for OPHELLIA PICs:

Telecom

Datacom

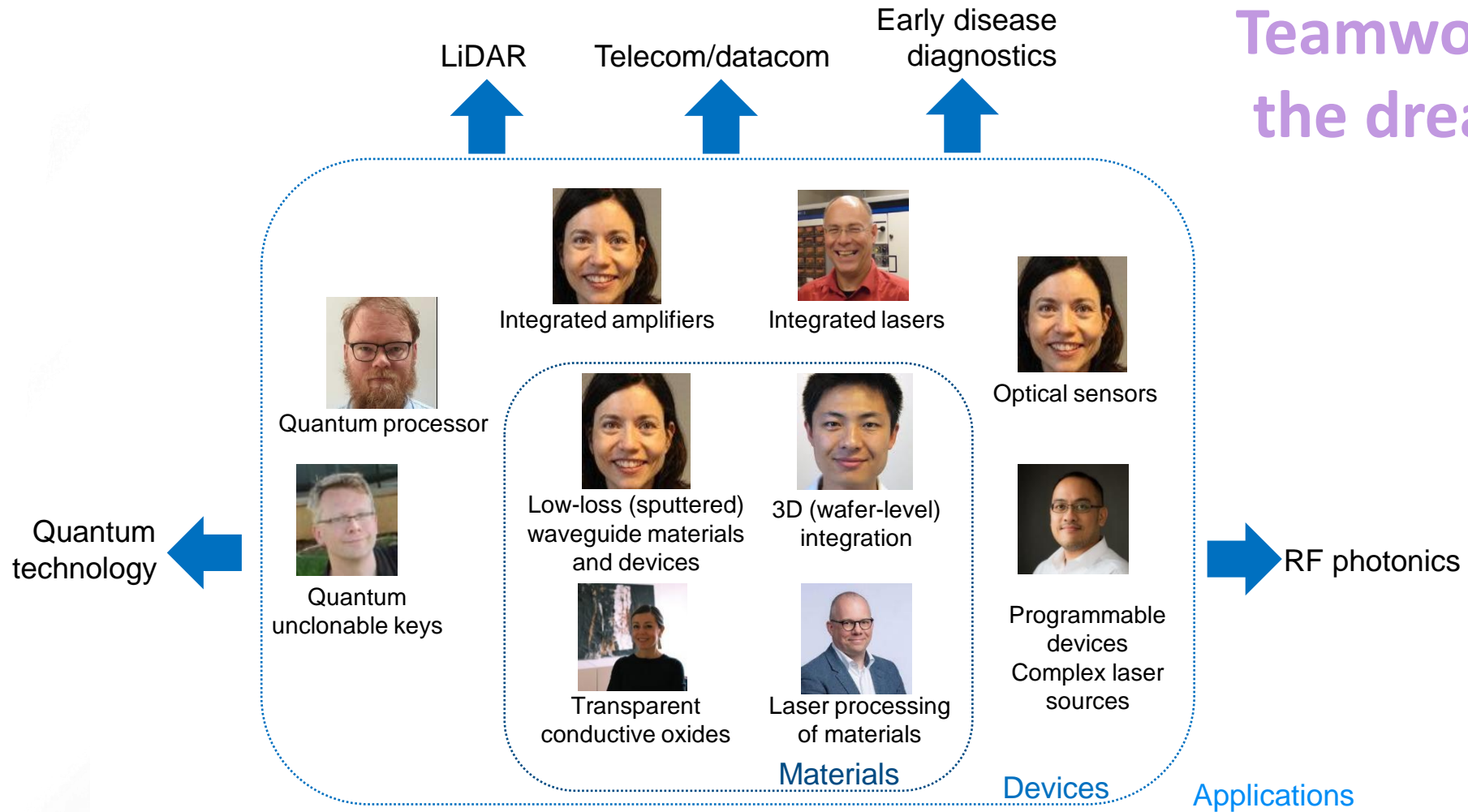
Spectroscopy

Quantum

Tematys
Exploration of photonics markets

Integrated LiDAR systems

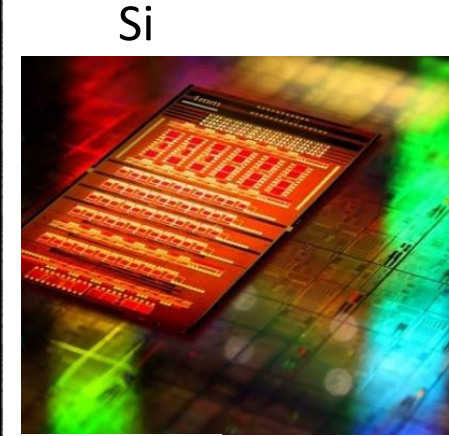
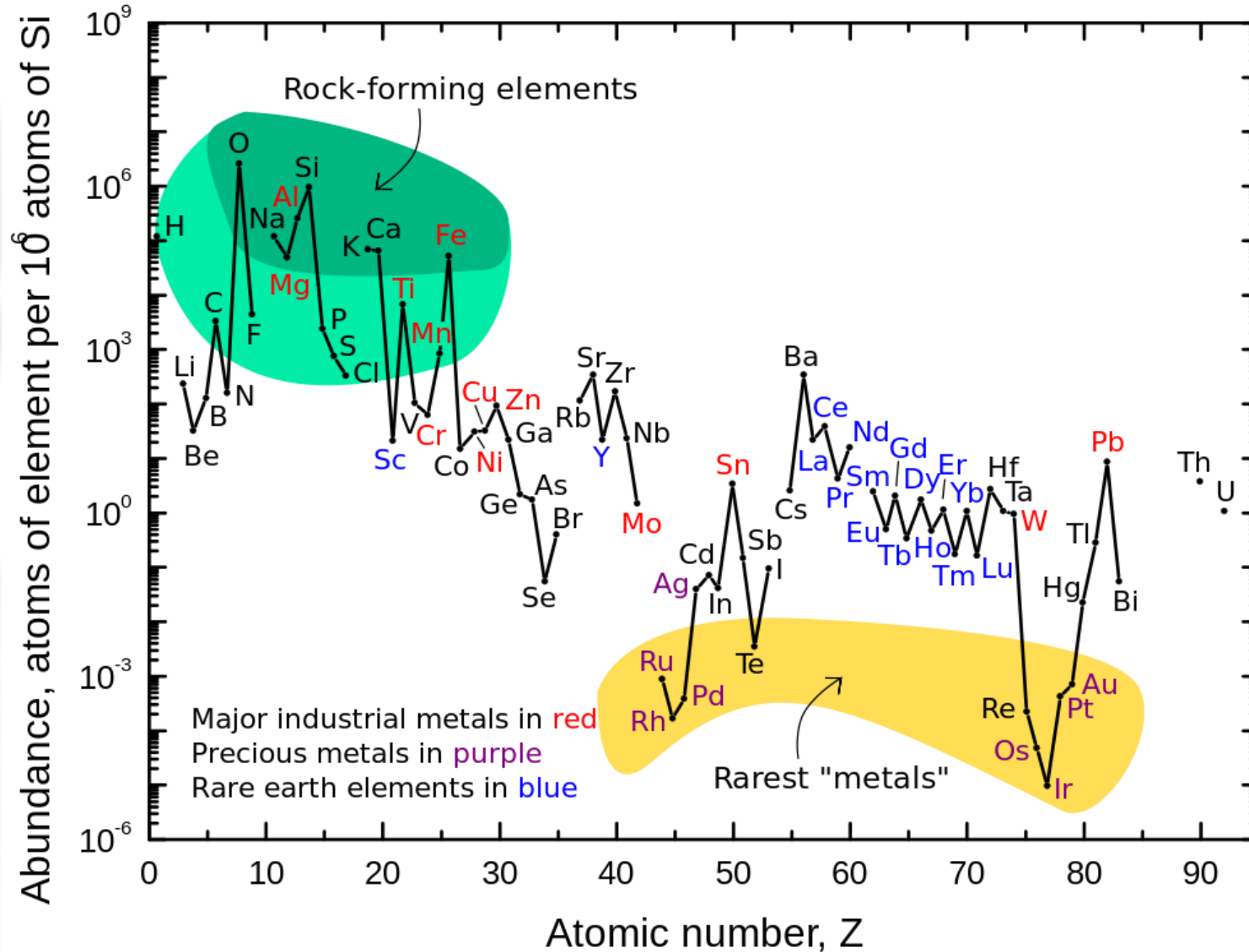
Teamwork makes the dreamwork!



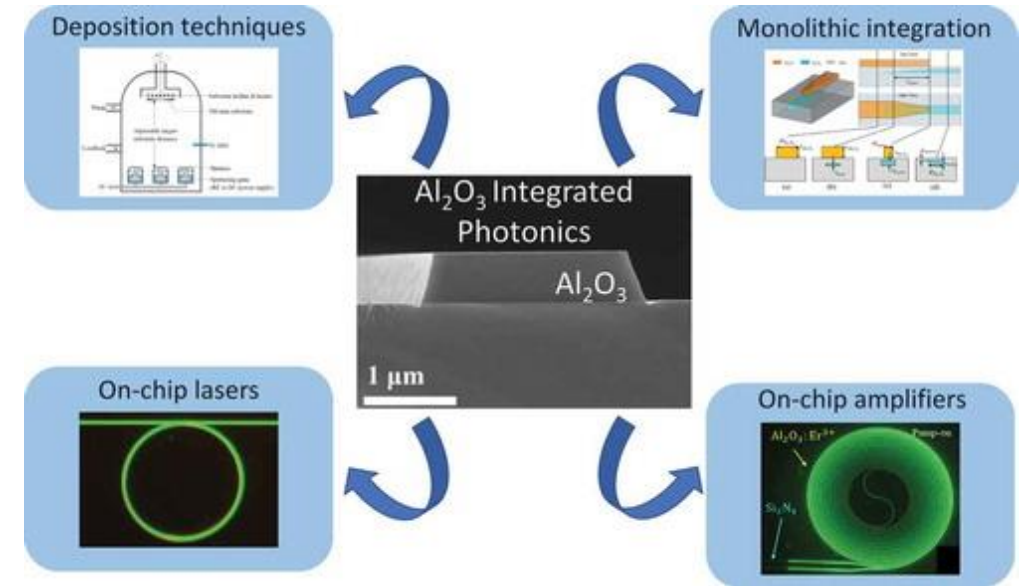


MESA+ INSTITUTE

- 1250 m² Class 10,000 cleanroom
- 1000 m² of specialized equipment
- Deposition (PVD + CVD), lithography, e-beam, SEM, TEM, etching, dicing, annealing etc.

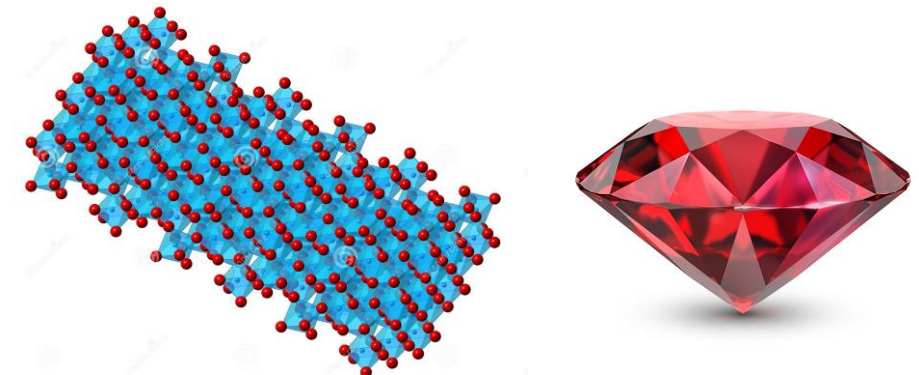


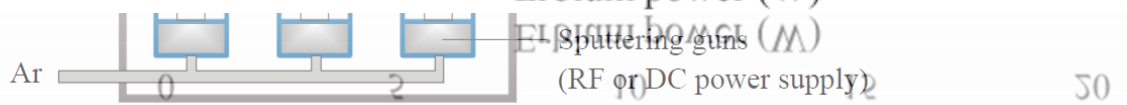
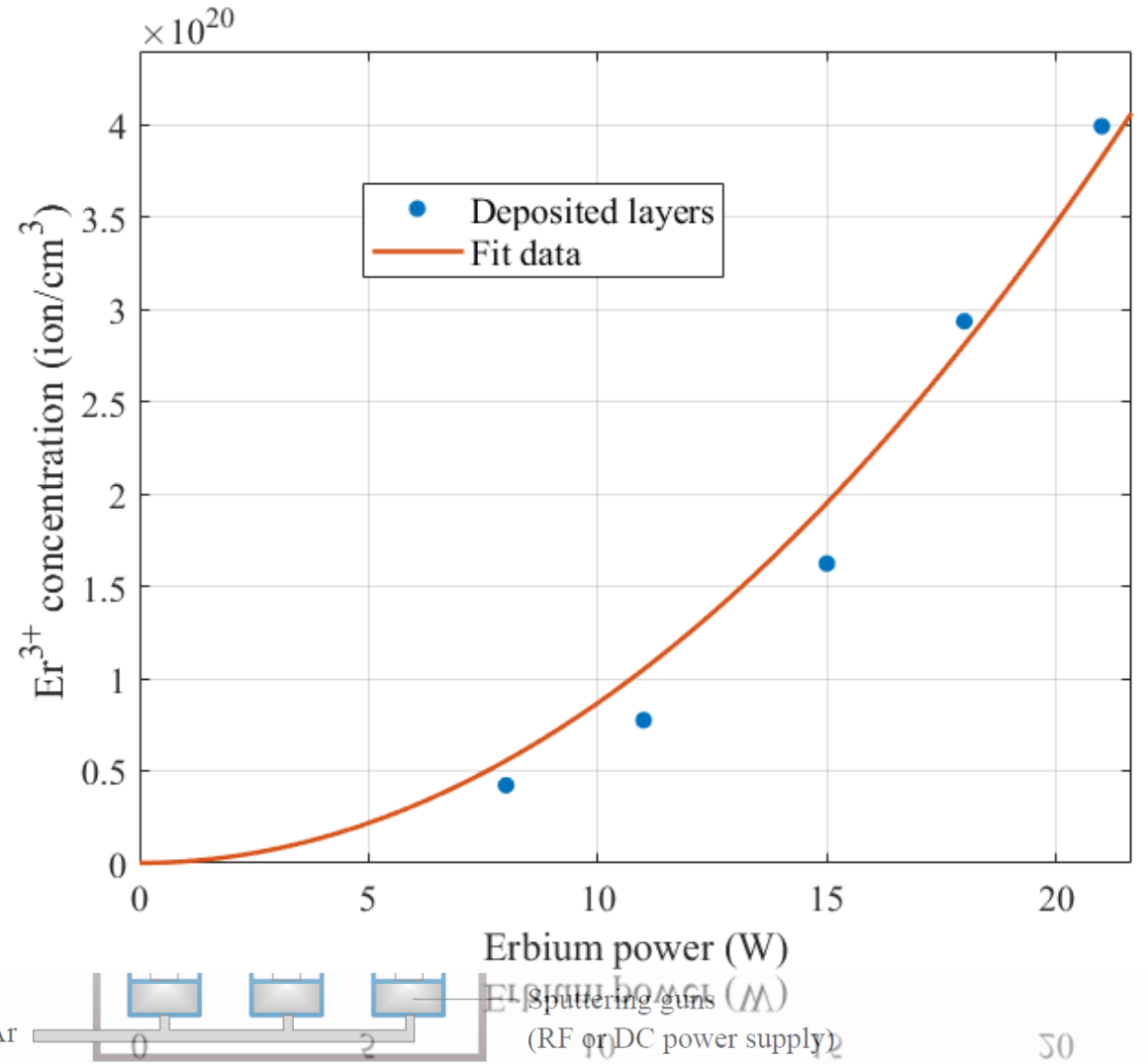
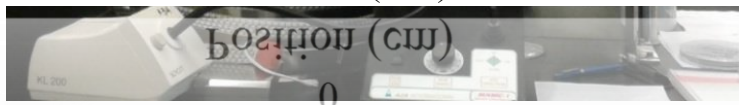
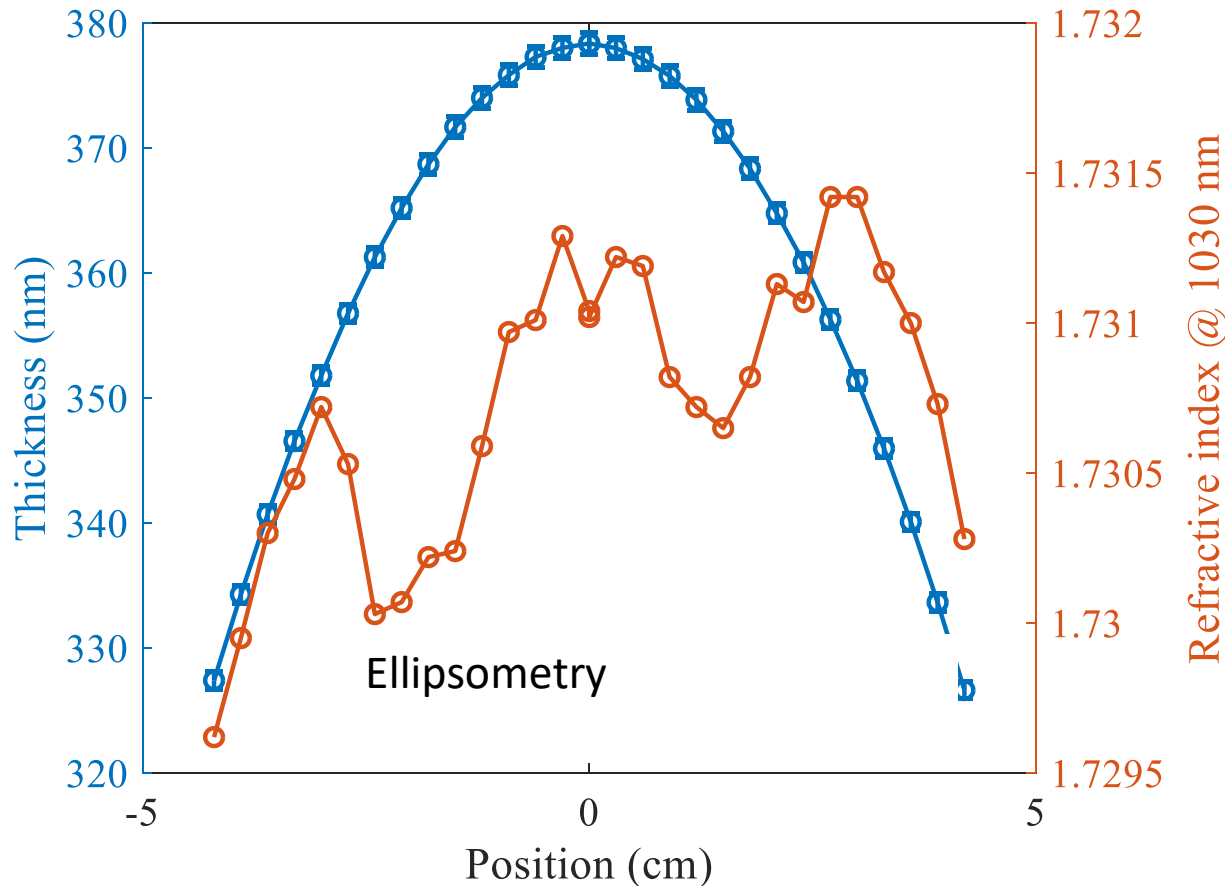
- Large transparency window: UV-mid-IR
- Low propagation losses: 5 dB/m
- Moderate refractive index: ~1.72 @1550 nm
- Wafer level deposition
- High rare-earth ion solubility
- In the Nanolab → RF reactive sputtering



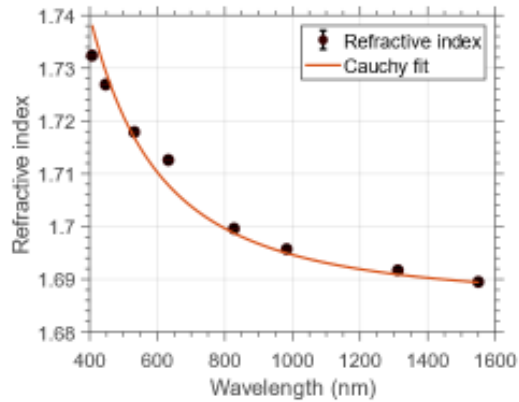
[Review: Hendriks et. al. , Advances in Physics: X, 6 (1), 1833753 (2021)]

- Rich history in photonics
- Naturally occurring in crystalline state as corundum, forming popular gems such as ruby and sapphire





REFRACTIVE INDEX AND
5% RELATIVE BIAS, 700°C SET S

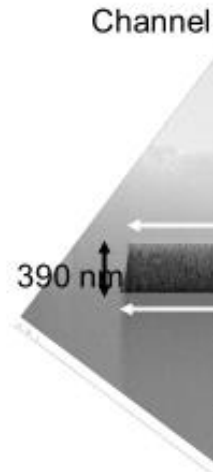


- 1.8 dB/c
- 0.025 dB

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CHANNEL
SETTINGS: 5%

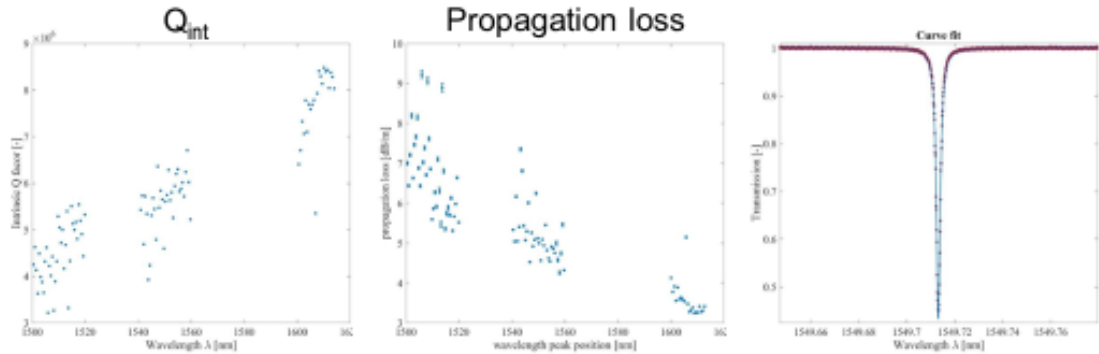


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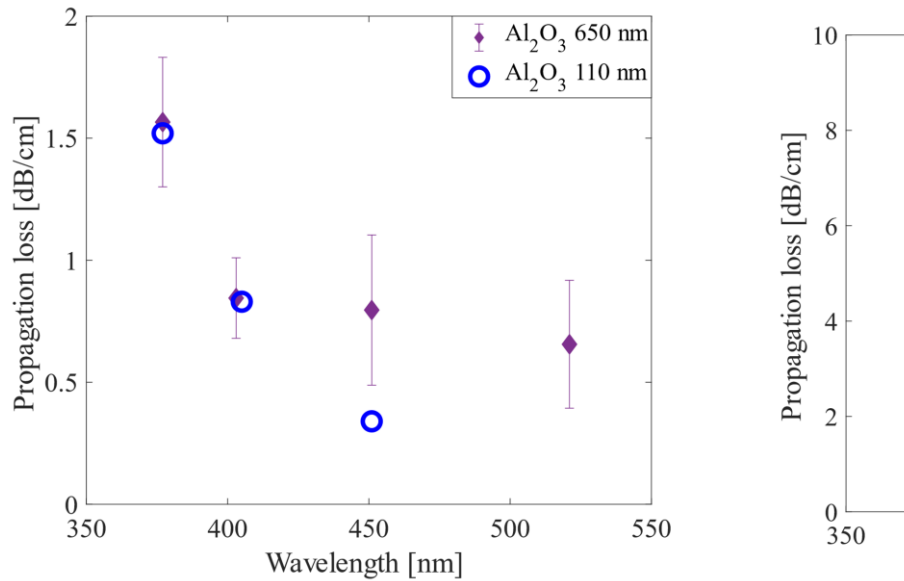
CHANNEL WAVEGUIDE CHARACTERIZATION

MICRORING RESONATOR RESONANCE ANALYSIS (400µm radius, 1200nm coupling gap)



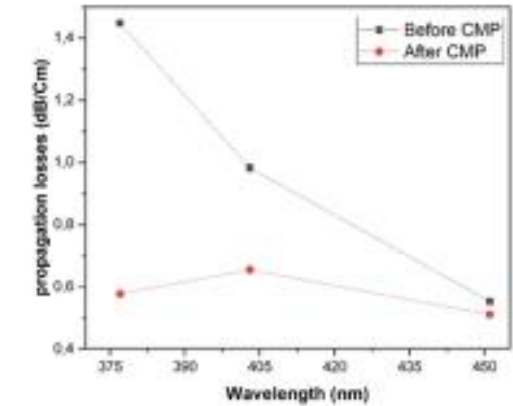
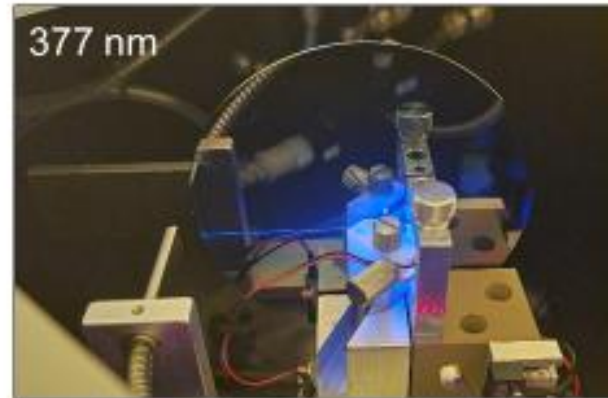
Propagation loss:
@1550nm: ~5 dB/m, $Q_{int} \sim 6 \times 10^6$
@1610nm: ~3dB/m, $Q_{int} \sim 8.5 \times 10^6$

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Al₂O₃ FOR OPERATION BELOW 400 nm

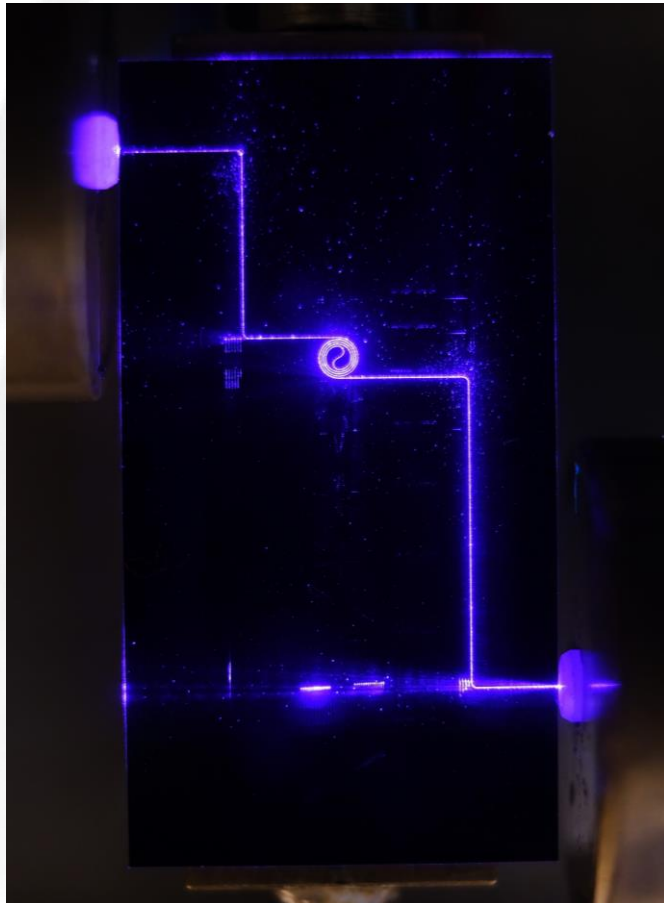
CHEMICAL MECHANICAL POLISHING



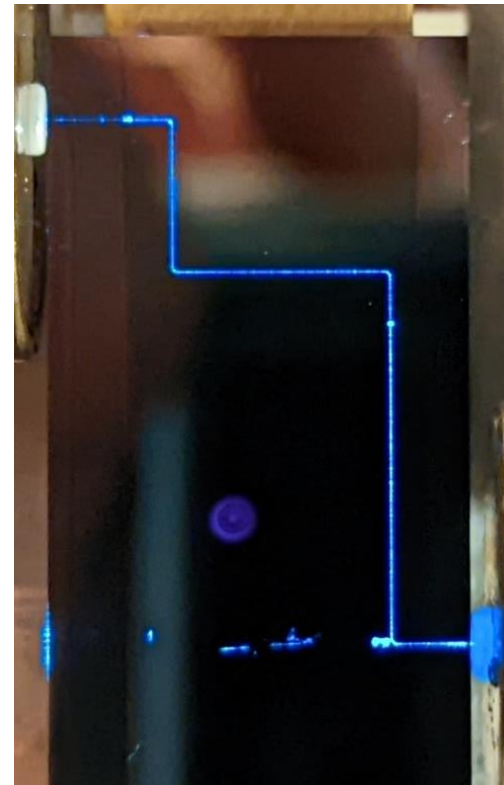
- 0.6 dB/cm loss at 377 nm after CMP (0.8 dB/cm improvement)
- Surface roughness measured with AFM (0.2nm RMS)

Soon to be sold from a foundry near you!

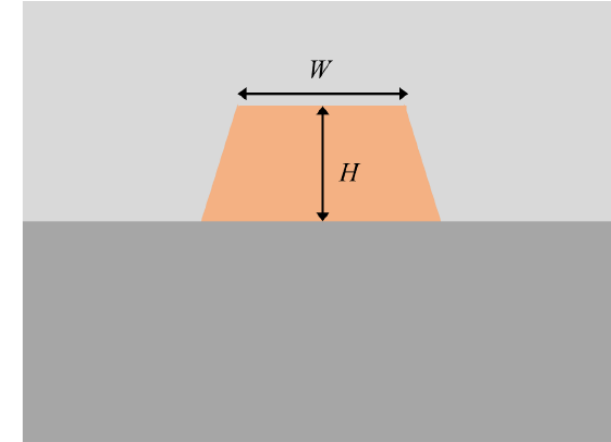
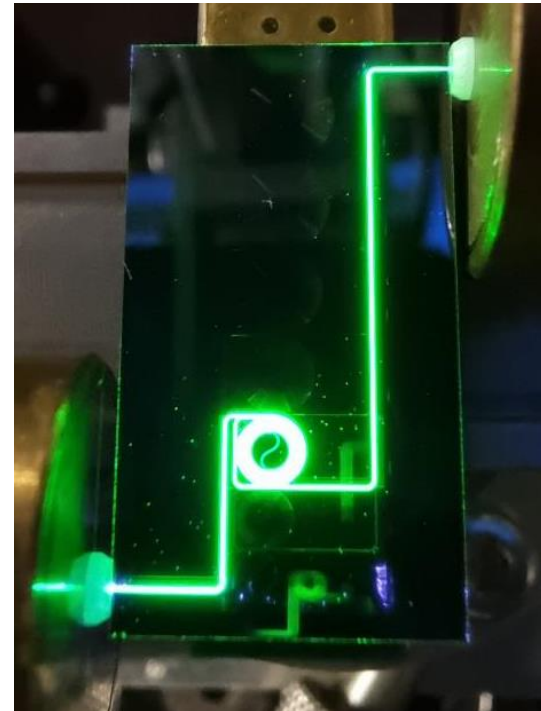
1.4 dB/cm losses measured at 375 nm



405 nm transmission



980 nm pumped $\text{Al}_2\text{O}_3:\text{Er}^{3+}$

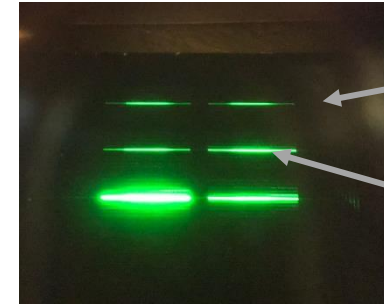


632 nm alignment



Double layer

A stack of two (or more) independent photonic layers interconnected by vertical adiabatic or resonant couplers

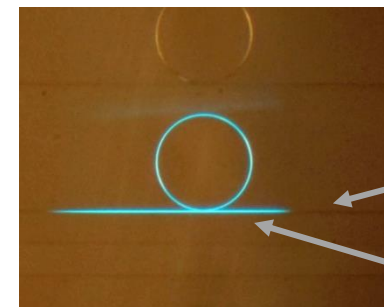


Si_3N_4

$\text{Al}_2\text{O}_3:\text{Er}^{3+}$

Single layer

Single passive photonic layer with incrustations of active gain material (photonic damascene process)
 → seamless transitions between layers



Al_2O_3

$\text{Al}_2\text{O}_3:\text{Yb}^{3+}$

[J. Mu, et. al. "Monolithic Integration of Al_2O_3 and Si_3N_4 Toward Double-Layer Active-Passive Platform," IEEE J. Sel. Top. Quant. Electron. 25, 8200911 (2019)]

[C. I. van Emmerik, et. al., "Single-layer active-passive Al_2O_3 photonic integration platform," Opt. Mater. Express 8, 3049-3054 (2018)]

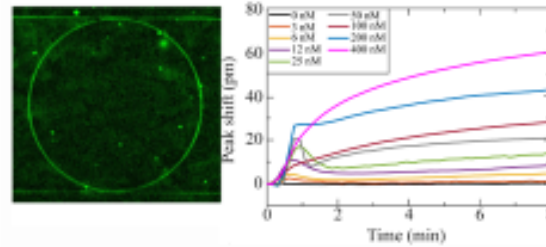
3D INTEGRATED
3D PRINTED



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DEVICES OPTICAL BIOSENSORS (I)

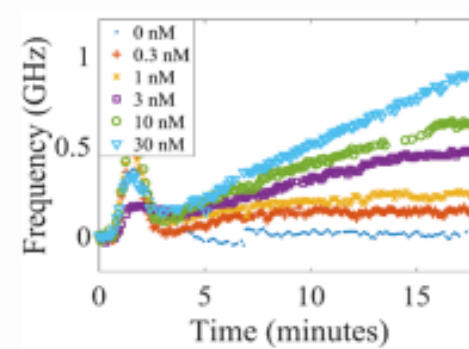
Passive Al₂O₃ microring sensors



- Bulk refractive index sensitivity: ~100 nm/RIU
- Noise: 0.05 pm
- Limit-of-detection (LOD) ~1e-6 RIU
- LOD 3 nM S100A4 protein

[M. De Goede, et. al., Optics Express (2019)]

Active Yb³⁺:Al₂O₃ microring sensors

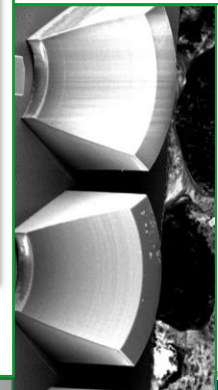
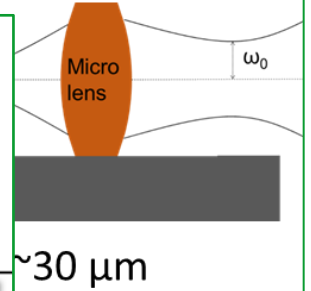


- Heterodyne detection
- Bulk refractive index sensitivity ~22nm/RIU
- Noise: ~ 0.026 pm
- LOD: ~3x10⁻⁶ RIU
- LOD 0.3 nM S100A4 protein

[M. De Goede, et. al., Optics Letters (2019)]
[M. De Goede, et. al., OSA Sensors, Invited presentation]

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Side view



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The objective of OPHELLIA is to develop novel materials and integration technology for the realization of innovative PIC^(a) building blocks to develop PIC-based laser sources for emerging TOF^(b) and FMCW^(c) LiDAR^(d) applications.

These LiDAR will be low cost and low size thanks to the high chip integration and tolerant packaging technology while, at the same time, exhibit the same or even higher performance than existing solutions.

TOF Source:

Key features:

- 700W peak power (100mW CW)
- Isolation: >25dB with <1dB loss
- Cost: <50% reduction

FMCW Source:

Key features:

- 200mW CW power
- Isolation: >25dB with <1dB loss
- Intrinsic linewidth <100Hz

Demonstrators:

Demo1: SICK
Sensor Intelligence.

- Safety in harbors and airports
- Industry 4.0

Demo2: RIEGL

- Autonomous robots/drones
- Industrial environments

Demo3: THALES

- Autonomous trains
- Safety

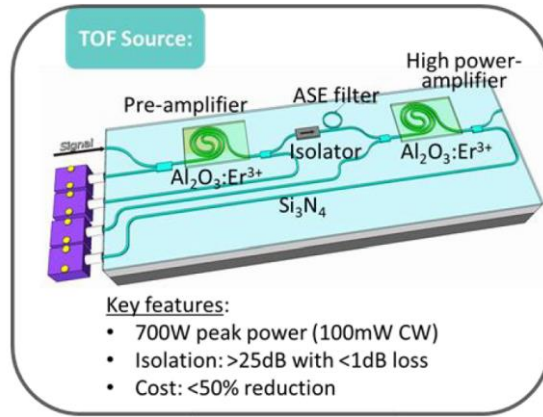
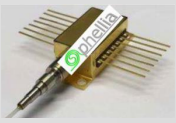
Other application fields for OPHELLIA PICs:

Telecom 	Datacom
Spectroscopy 	Quantum

Tematys
Exploration of photonics markets

PIC/packaging partners:

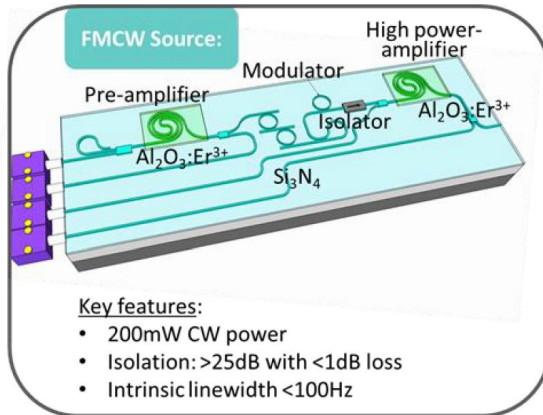
^(a)PIC: Photonic integrated circuit ^(b)TOF: Time of flight ^(c)FMCW: Frequency-modulated continuous-wave ^(d)LiDAR: Light detection and ranging



Safety in harbour and airport / Industry 4.0

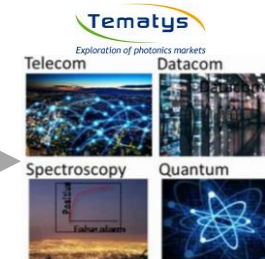


Autonomous robots/Drones
Industrial applications



Autonomous train / Traffic safety

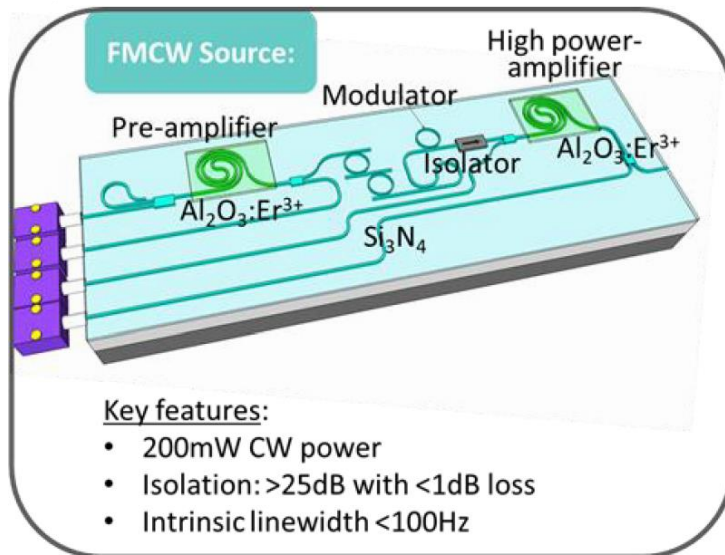
New material, PIC blocks,
packaging...



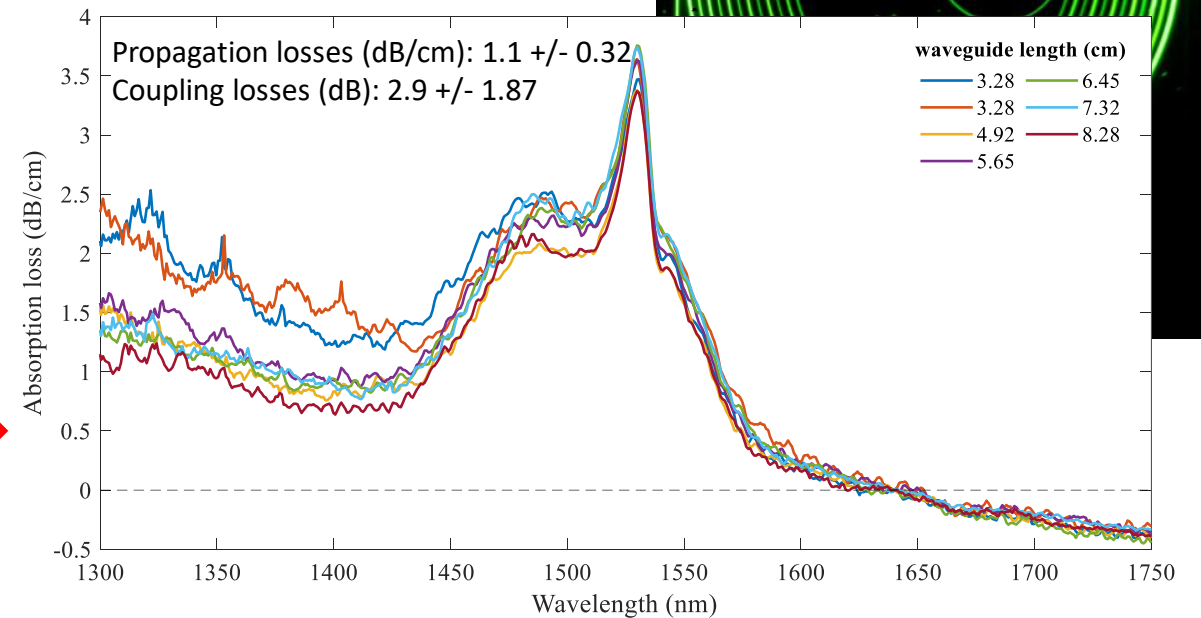
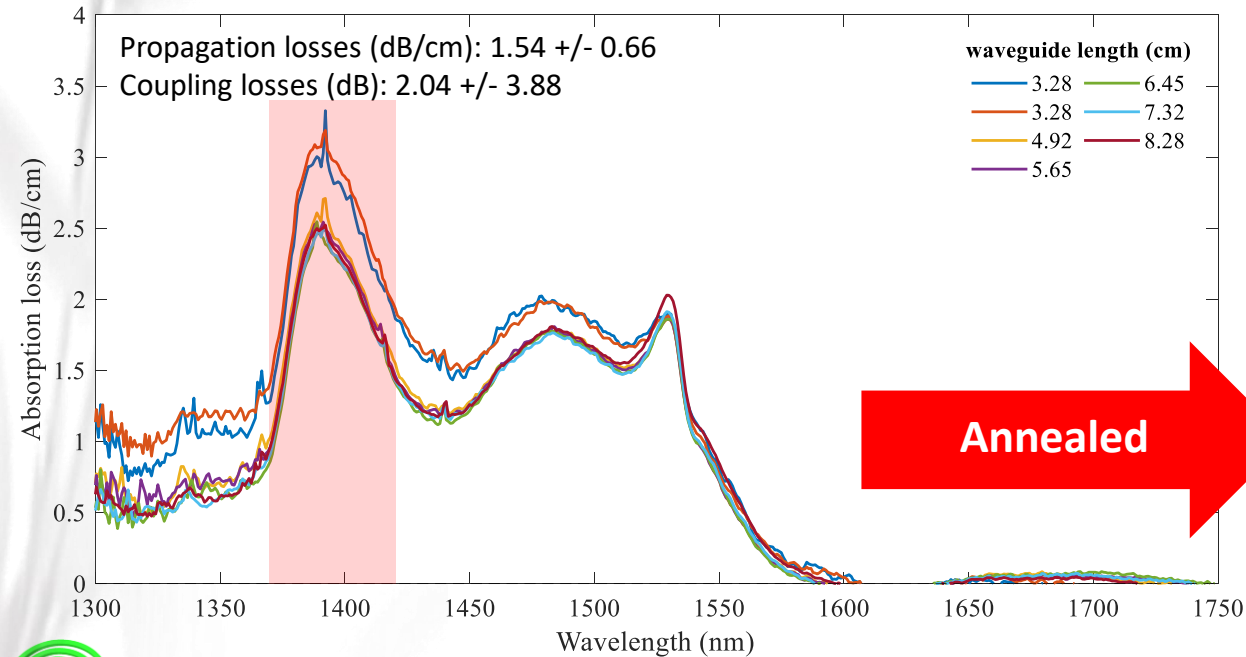
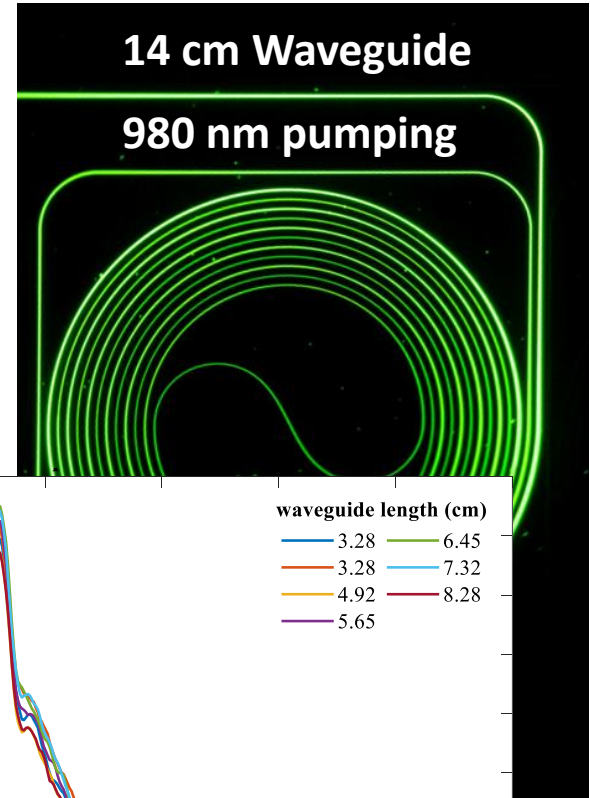
Exploitation of the results in other
potential applications



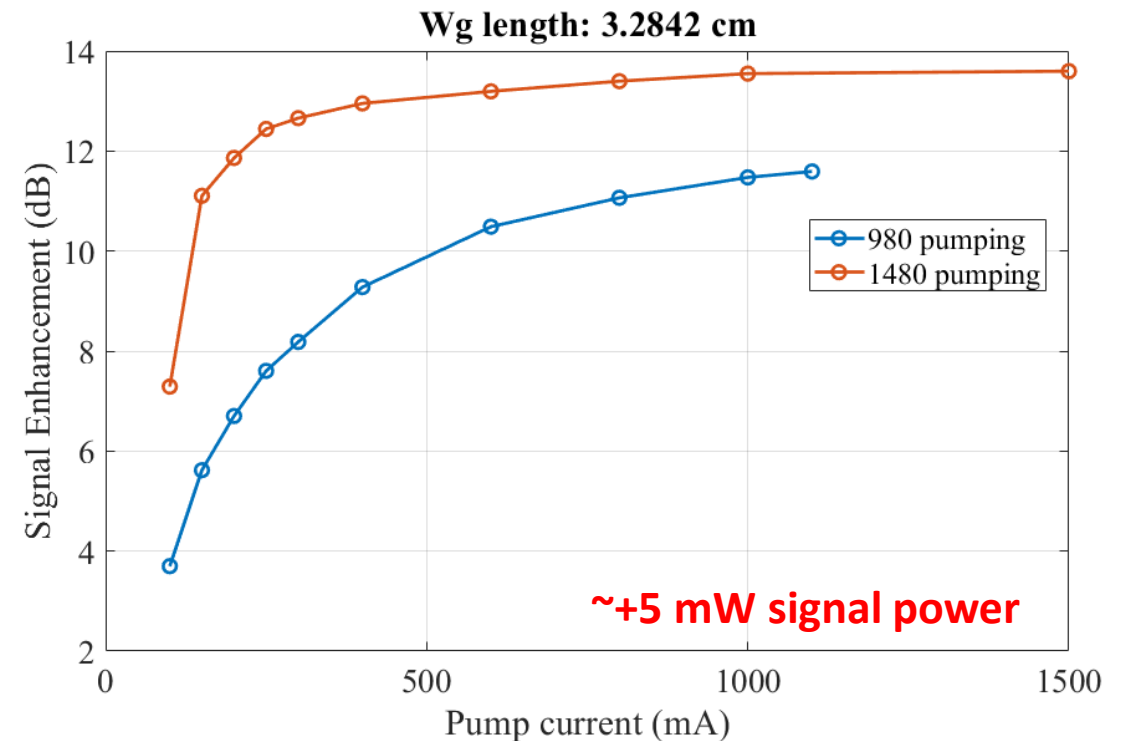
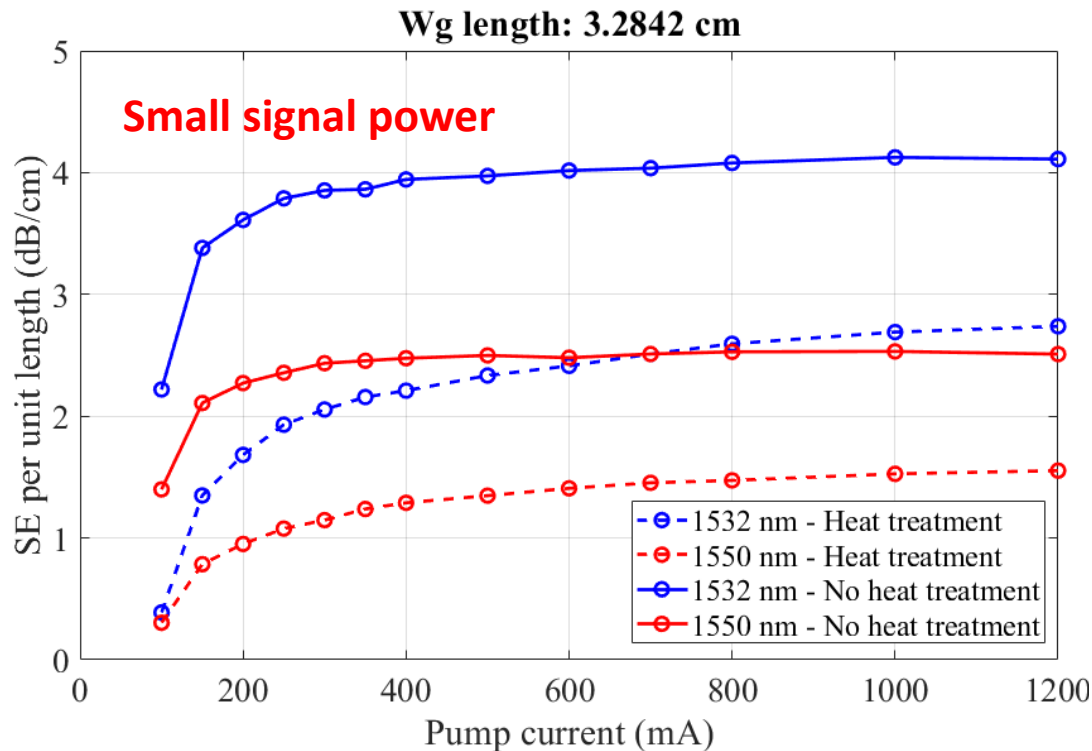
- Fully integrated product combined with cladding which may require annealing
- Amorphous alumina suffers mechanical failure from annealing – polycrystalline host provides higher thermal budget
- Polycrystalline host provides lower losses across broader wavelength range



- Initial results limited by absorption and propagation losses
- OH likely leading to reduction of lifetime and 1380 nm absorption – clustering of Erbium ions present
- Annealing high thermal budget host intended for reduction of losses. 1100 °C removes OH signature, but crystallizes host – fast decay (short lived lifetime) observed

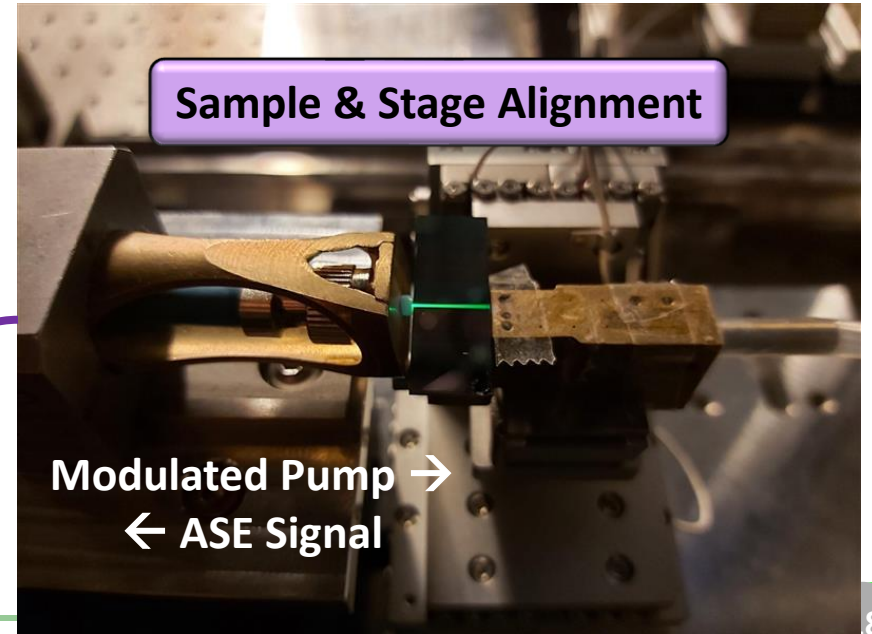
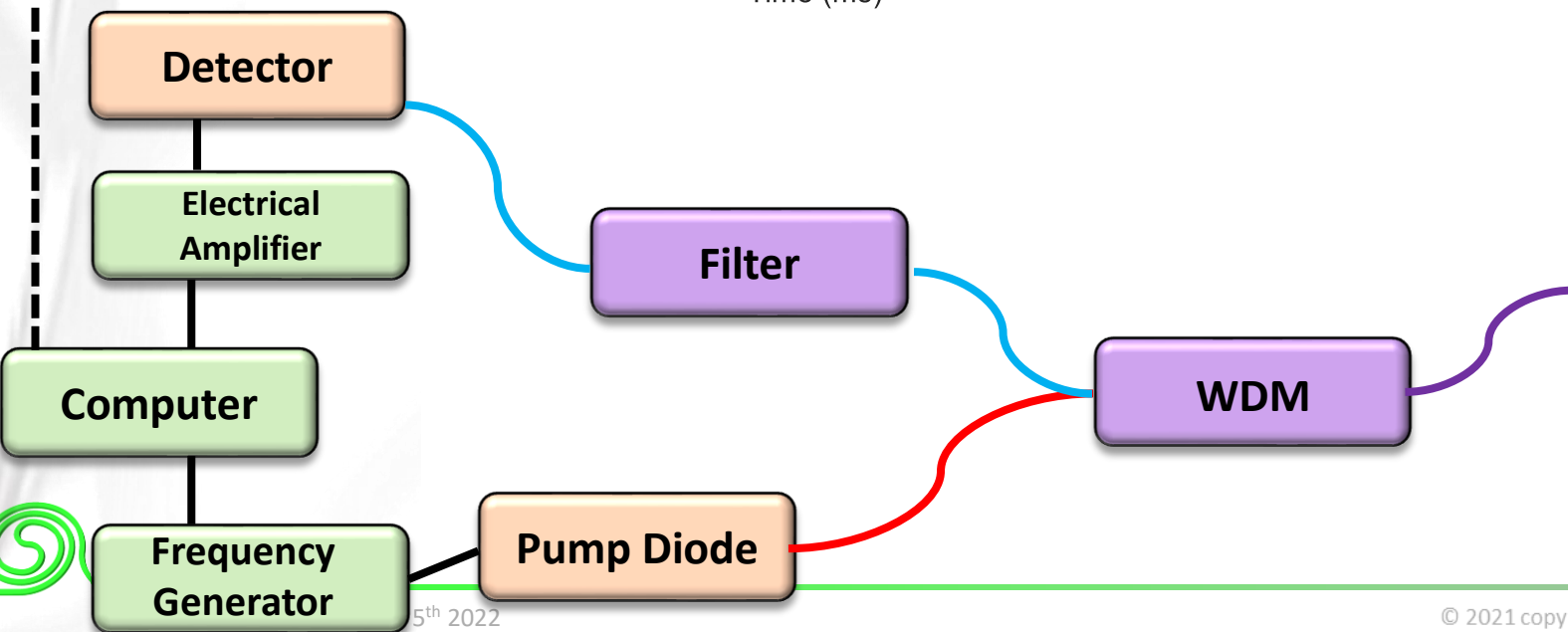
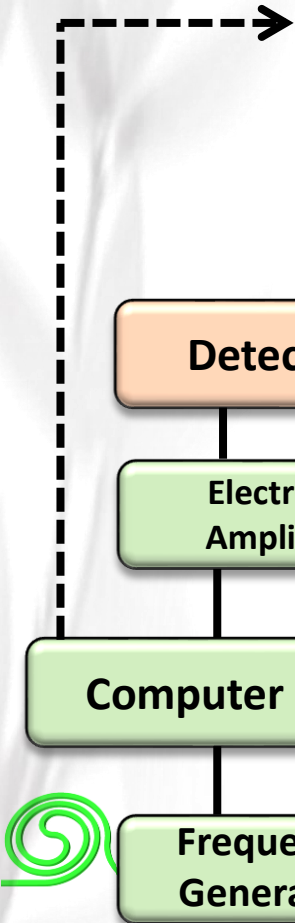
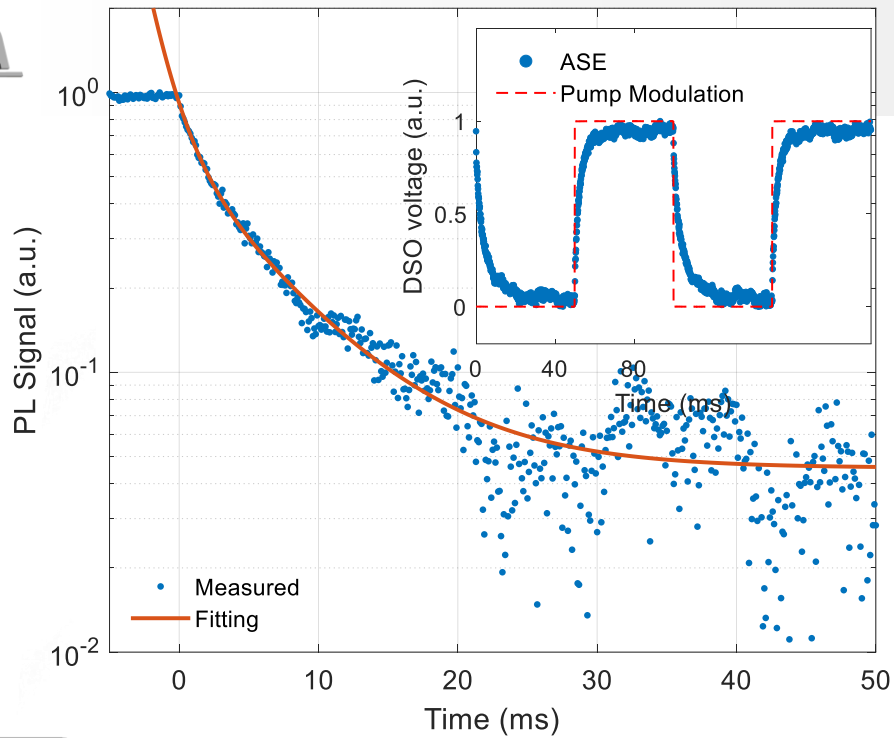


- High output power primary goal for project (100 mW+ at 1550 nm)
- Current high temperature heat treatment introduces high absorption losses, and fast decay
- Stable lifetime across fabrication steps required



PL SETUP

Planar or waveguide modes excited via 976 nm pump, back reflected ASE signal filtered through WDM to photodetector (top collection method possible with new fibers coming soon...)



- Expected O-H contamination from storage of samples in ambient
- Lifetime measurements also used to determine if cladding introduces O-H leading to fast decay (quenching)
- Annealing too high reduces lifetime



Sample State	Lifetime (ms)
'Old' fully fabricated	4.81 +/- 0.14
'Old' fully fabricated (annealed)	2.80 +/- 0.39
As deposited (slab mode)	7.24 +/- 1.44
Etched (multi-mode waveguides)	6.91 +/- 0.55
Cladded	6.64 +/- 1.65
Heat Treatment (650 °C)	6.56 +/- 2.87

Measurements repeated over 30 days?
Further passivation required?
To be measured.....

Ambient storage

Lifetime reliable indicator for clustering?
Pump absorption measurements coming soon....

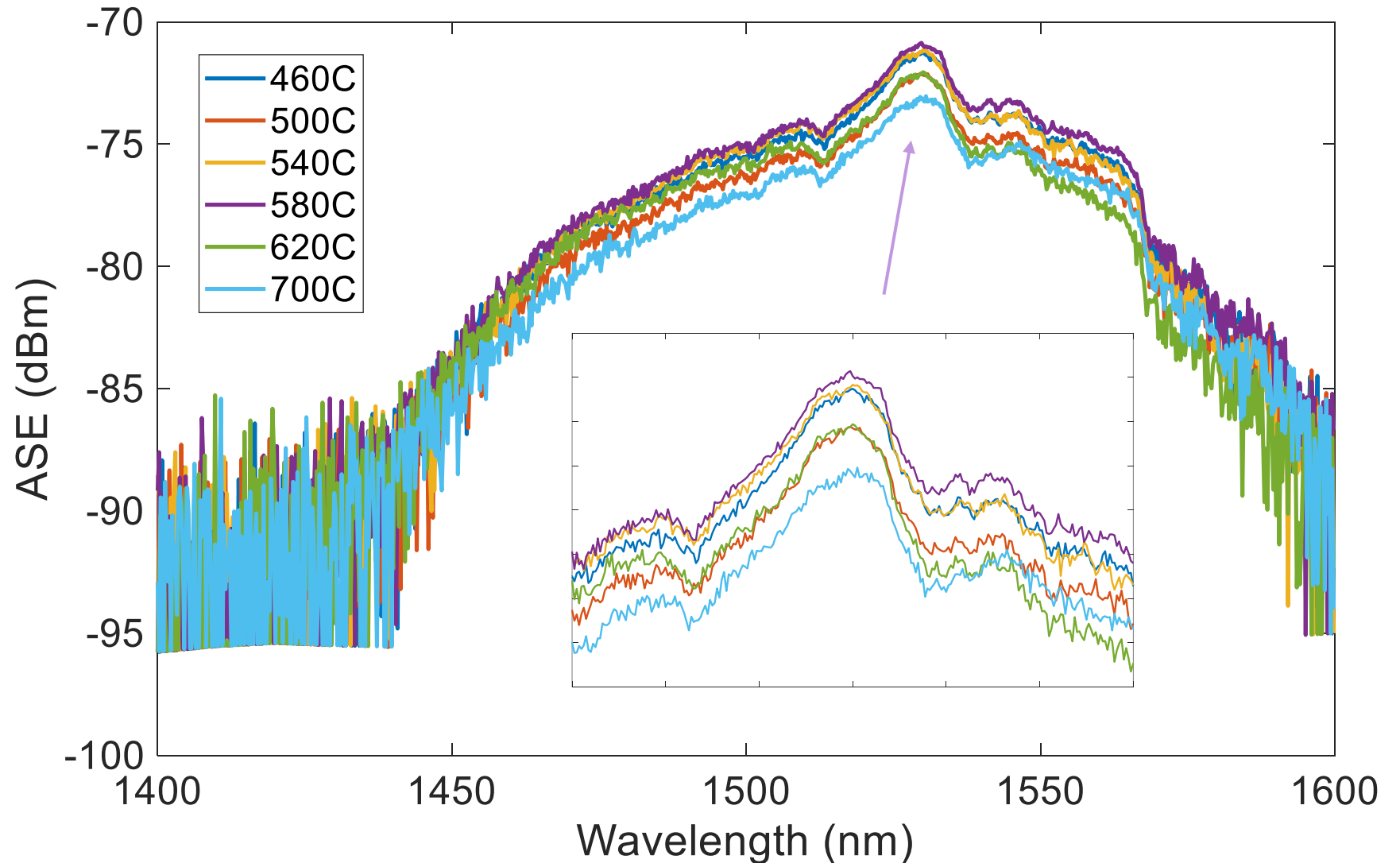
Nitrogen purged cabinet

Are ions clustering at grain boundaries?
Is erbium oxide forming in the matrix?...

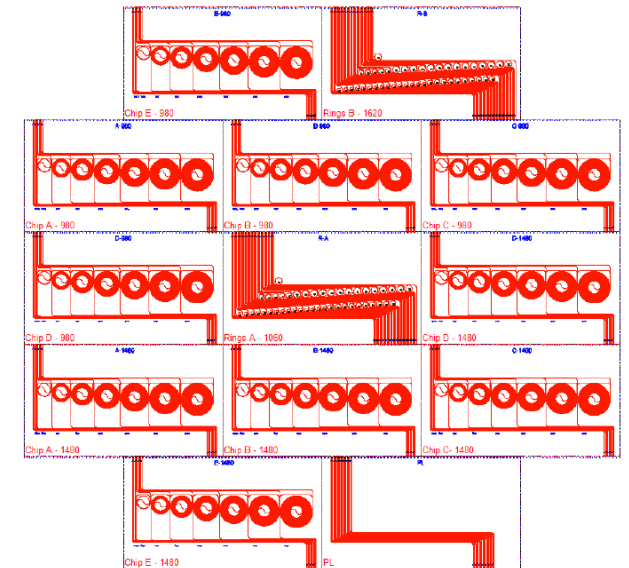
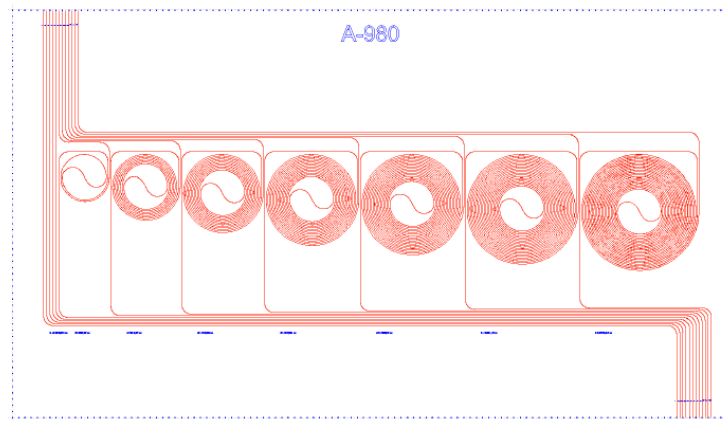
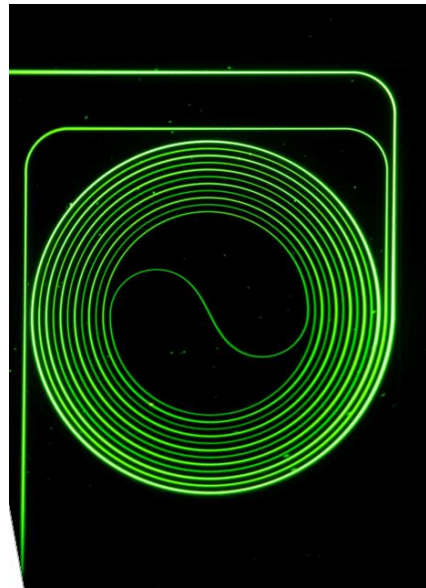


Film ID	Refractive index
	1030 nm
CO220603	1.6664
CO220601	1.6660
CO220602	1.6680
CO220604	1.6700
CO220605	1.6900
CO220606	1.7313

Waveguides etched, cladded, unannealed (multi-mode)	Fi
	CO
	CO



- New round of chips ready for measuring with nitrogen purged storage during fabrication
- Systematically investigate more temperatures to see affect on signal enhancement, propagation and absorption losses, quenching, and lifetime
- Quantify crystallinity with TEM & XRD
- Investigate variety of dopant concentrations to achieve highest gain and output power using 1480 nm pumping





Programme(s): H2020-EU.2.1.1. - INDUSTRIAL LEADERSHIP - Leadership in enabling and industrial technologies - Information and Communication Technologies (ICT)

Topic(s): ICT-37-2020 - Advancing photonics technologies and application driven photonics components and the innovation ecosystem

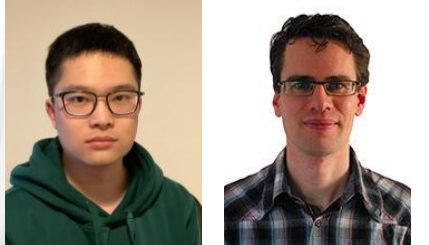
Call for proposal: H2020-ICT-2020-2

Funding Scheme: RIA - Research and Innovation action

More information:

<https://lidar-ophellia.eu>

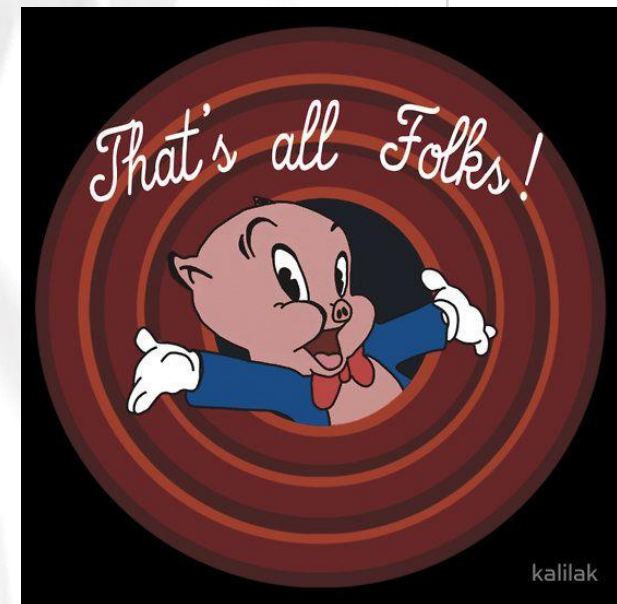
<https://cordis.europa.eu/project/id/101017136>



PARTNERS

UNIVERSITEIT TWENTE NL (COORD.)	NL	
KEOPSYS INDUSTRIES	FR	
LIONIX INTERNATIONAL BV	NL	
VANGUARD AUTOMATION	DE	
THALES France	FR	
SICK AG Germany	DE	
RIEGL RESEARCH FORSCHUNGSGESELLSCHAFT MBH	AT	
TEMATYS	FR	

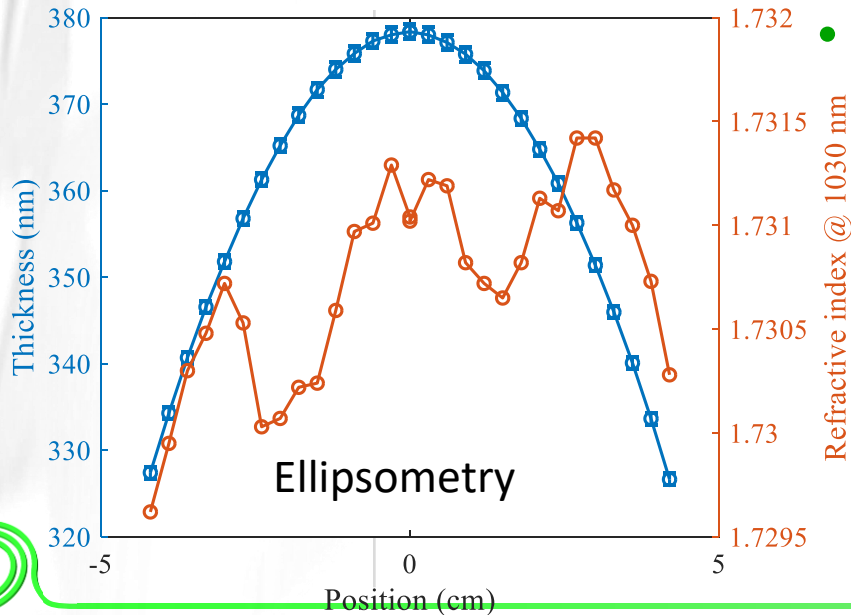
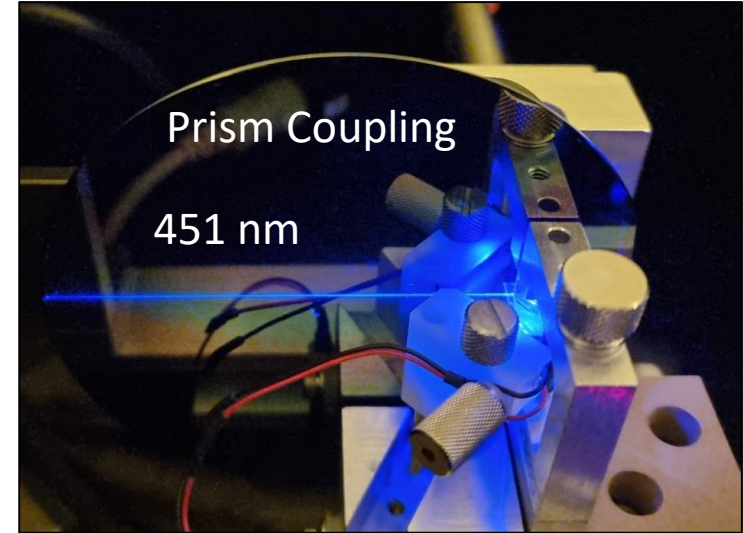
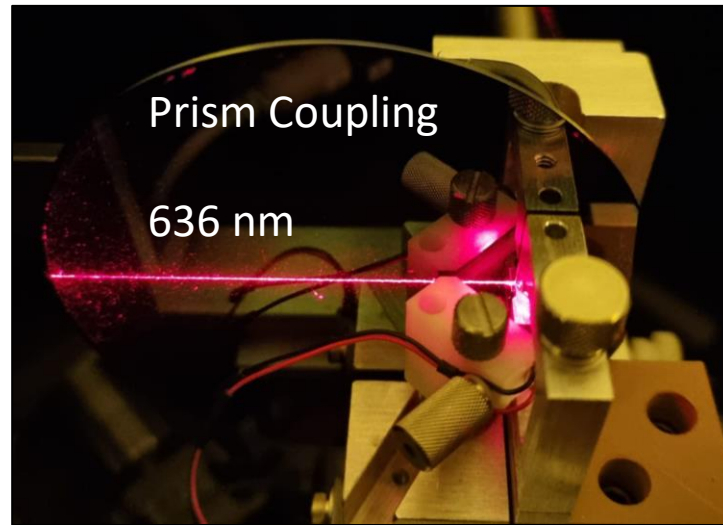




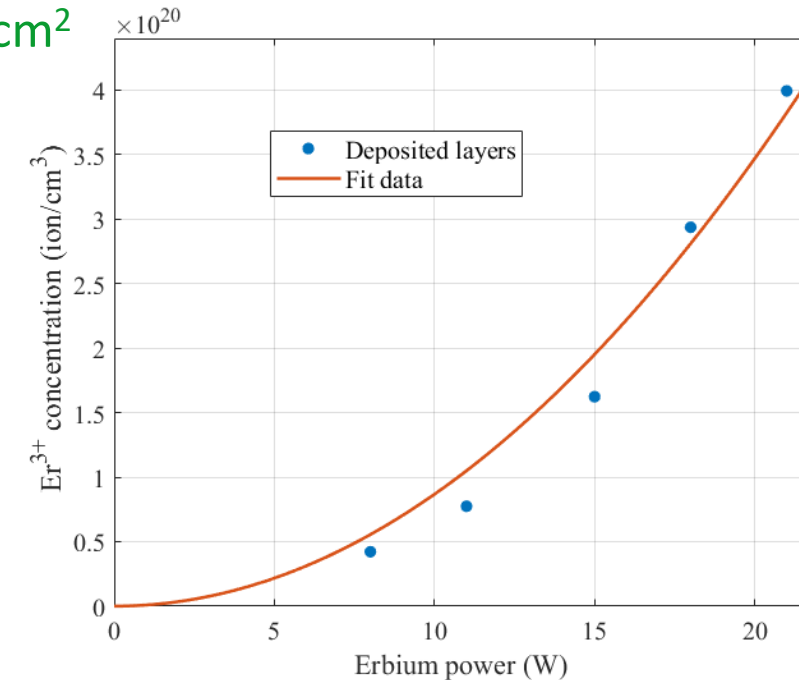
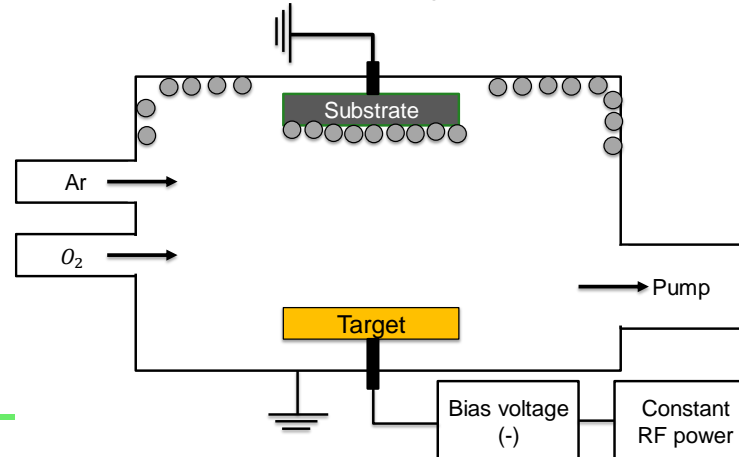
Thank you for your attention! Happy to take questions.



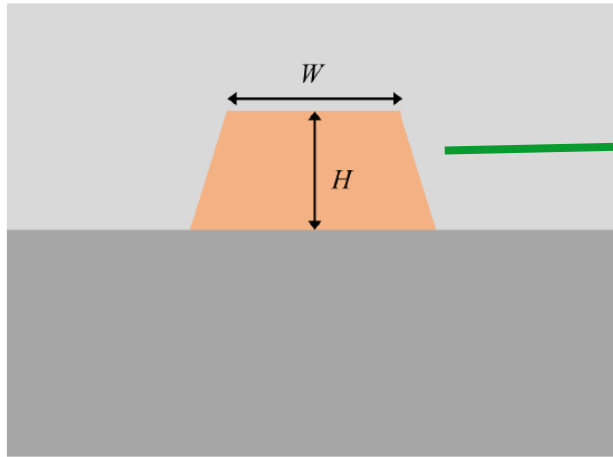
Er Power (W)	15
T (°C)	740
Dep. rate (nm/min)	4.44
n (@ 1030 nm)	1.731
Losses @ 451 nm (dB/cm)	2.79
Losses @ 636 nm (dB/cm)	0.73
Losses @ 978nm (dB/cm)	1.13



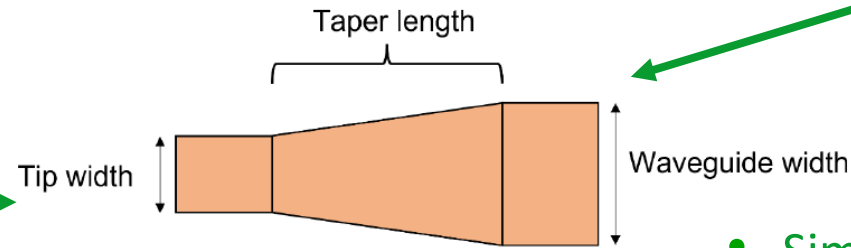
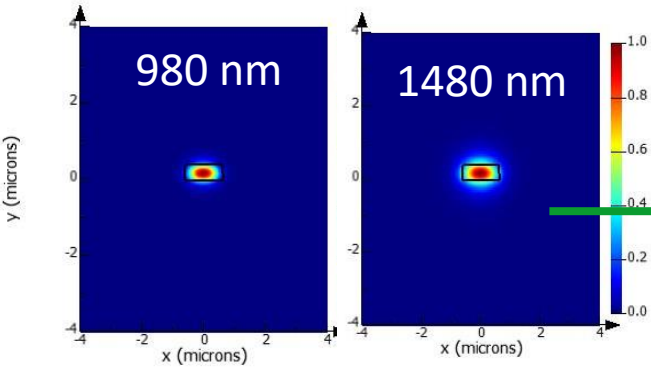
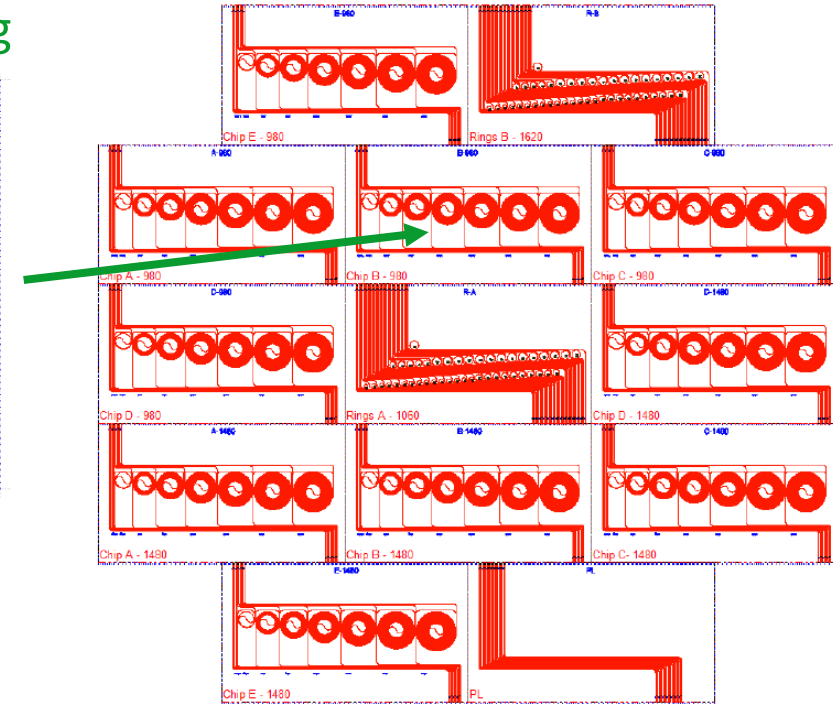
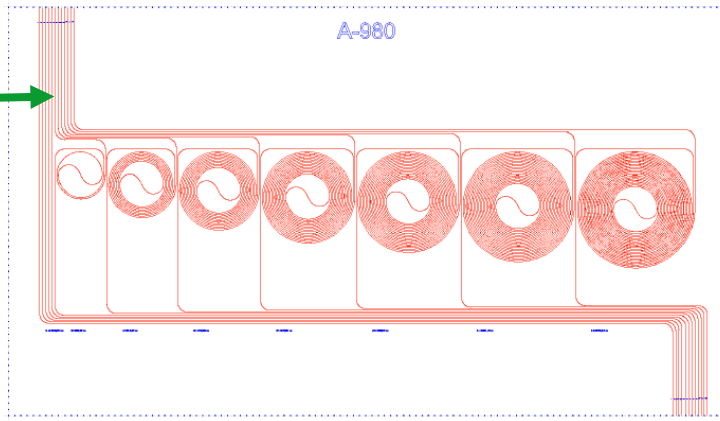
• Er³⁺ concentration of 1.62×10^{20} ion/cm² fit from RBS



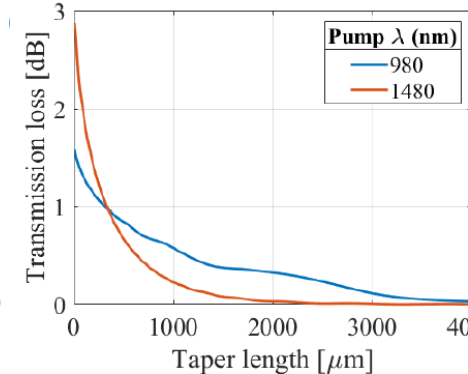
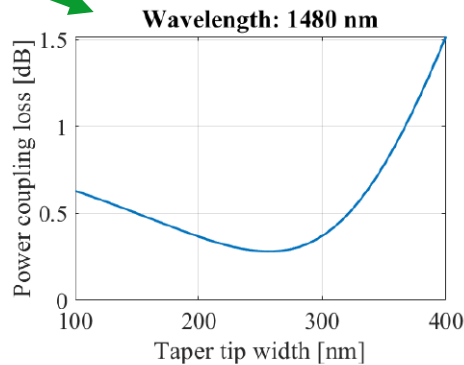
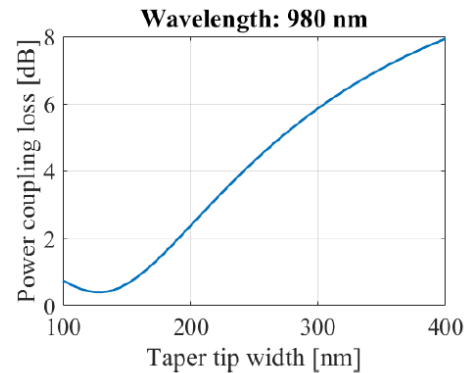
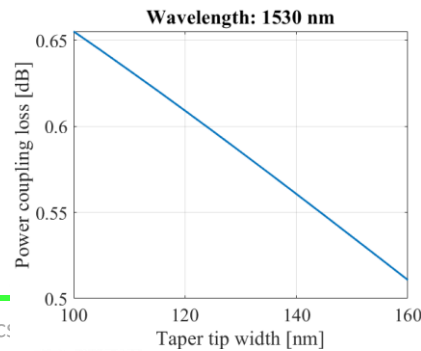
- E-beam, RIE (BCl₃-HBr), CVD (SiO₂), Dicing



- Thermal SiO₂
- Er-doped Al₂O₃
- PECVD SiO₂



- Simulations to ensure efficient pump coupling
- 140 nm used for 980 nm coupling

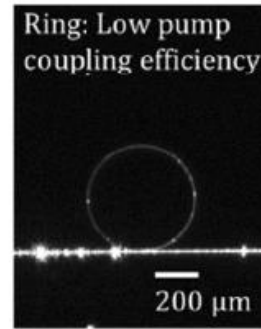
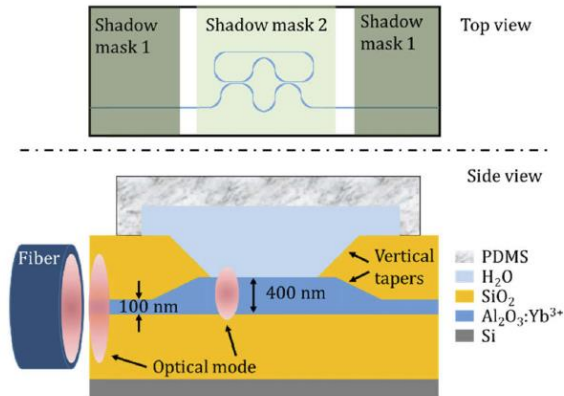




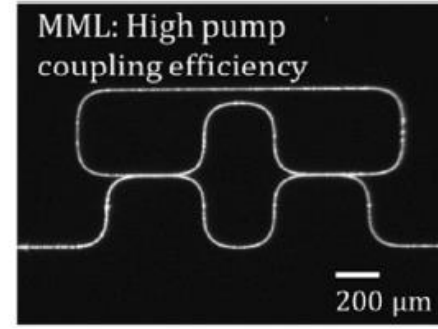
Dr. Lantian Chang
Assistant Professor
Optical Sciences

Modular microring laser cavity sensor (Yb³⁺)

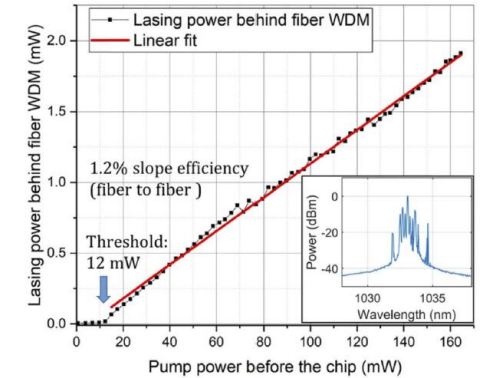
Vol. 29, No. 2 / 18 January 2021 / Optics Express



VS.

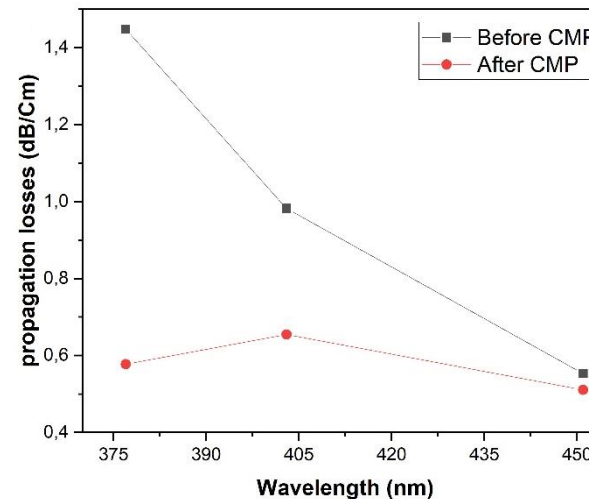
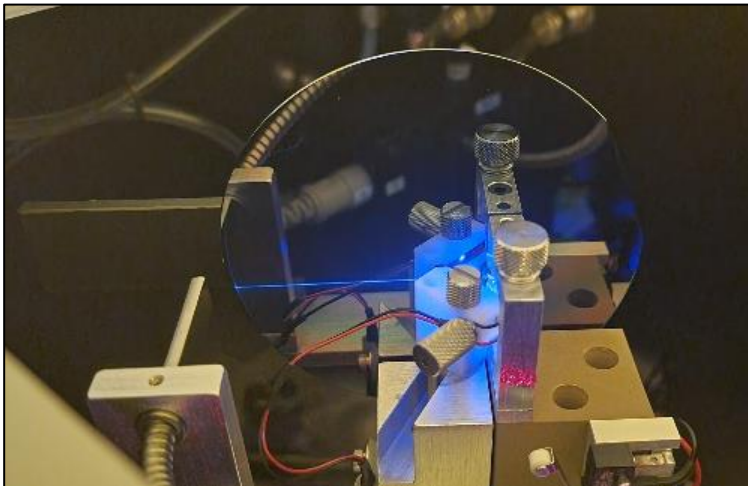


- Fiber-to-fiber slope efficiency of up to 1.2%
- 3 σ limit of detection (LOD) of 3.1×10^{-7} RIU



Low-loss chemically mechanically polished Al₂O₃ thin films for UV integrated photonics

4 May 2022 / European Conference on Integrated Photonics



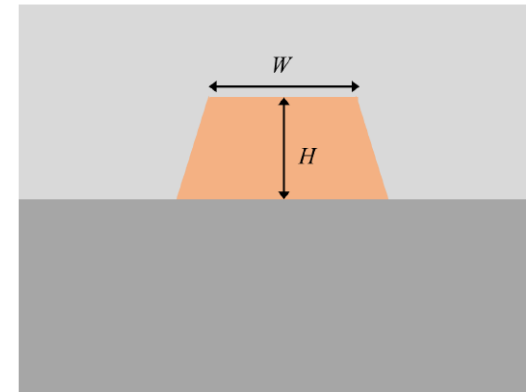
- 0.6 dB/cm loss at 375 nm after CMP (0.8 dB/cm improvement)
- Surface roughness measured with AFM



Soheila Mardani Mehrabad
PhD Candidate at University
of Twente



- First study focusing on new high index (~ 1.731 @ 1030 nm) films deposited at high temperature (700+ °C)
- Initial deposited wafers used for verifying choice between 980 vs 1480 nm pumping
- After initial gain & spectroscopy measurements, samples are to be annealed and re-measured
- Multi-layer integration with Si_3N_4 fabrication after optimization of $\text{Al}_2\text{O}_3:\text{Er}^{3+}$ strip waveguides



- Thermal SiO_2
- Er-doped Al_2O_3
- PECVD SiO_2

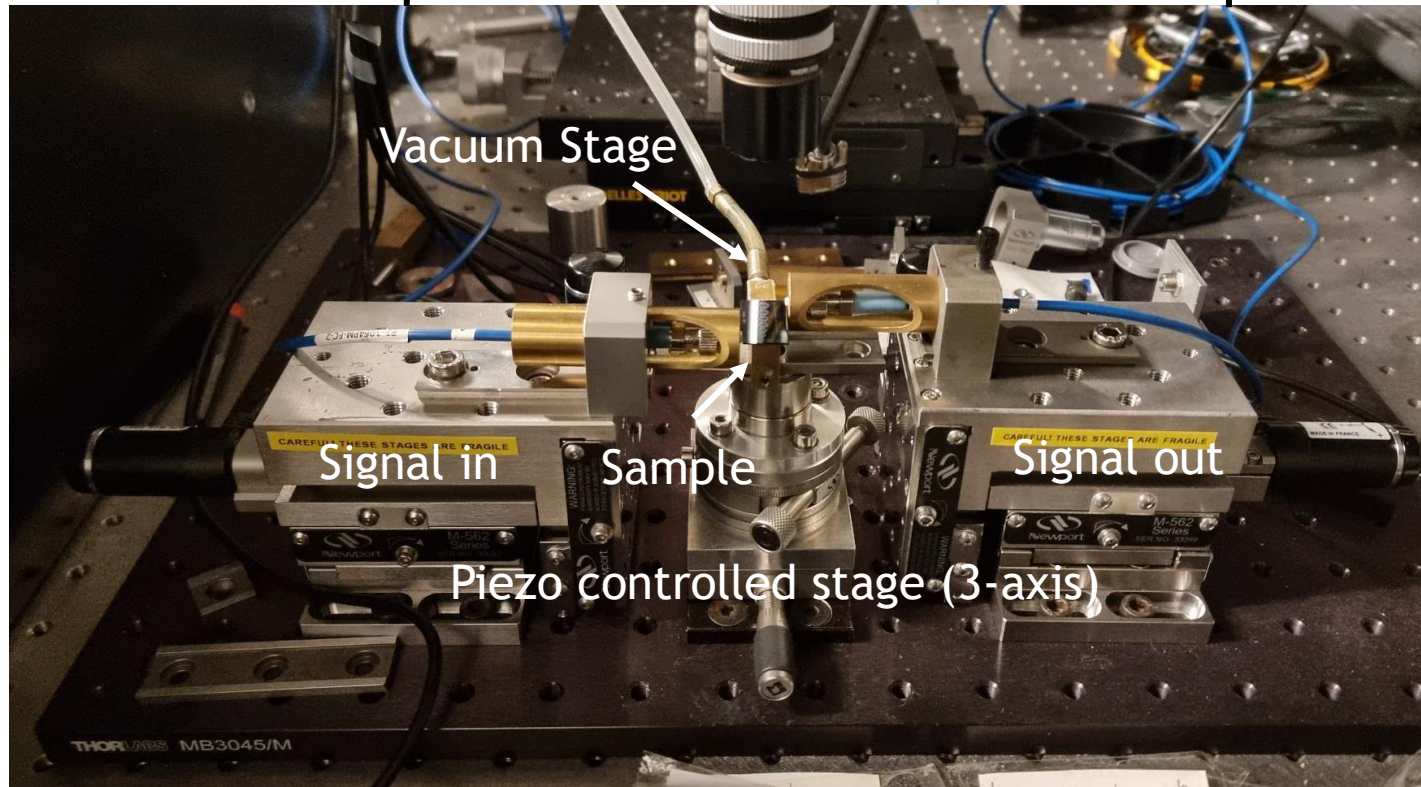


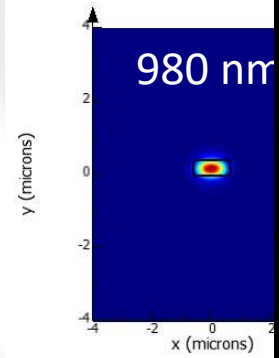
Carlos Osornio-Martinez
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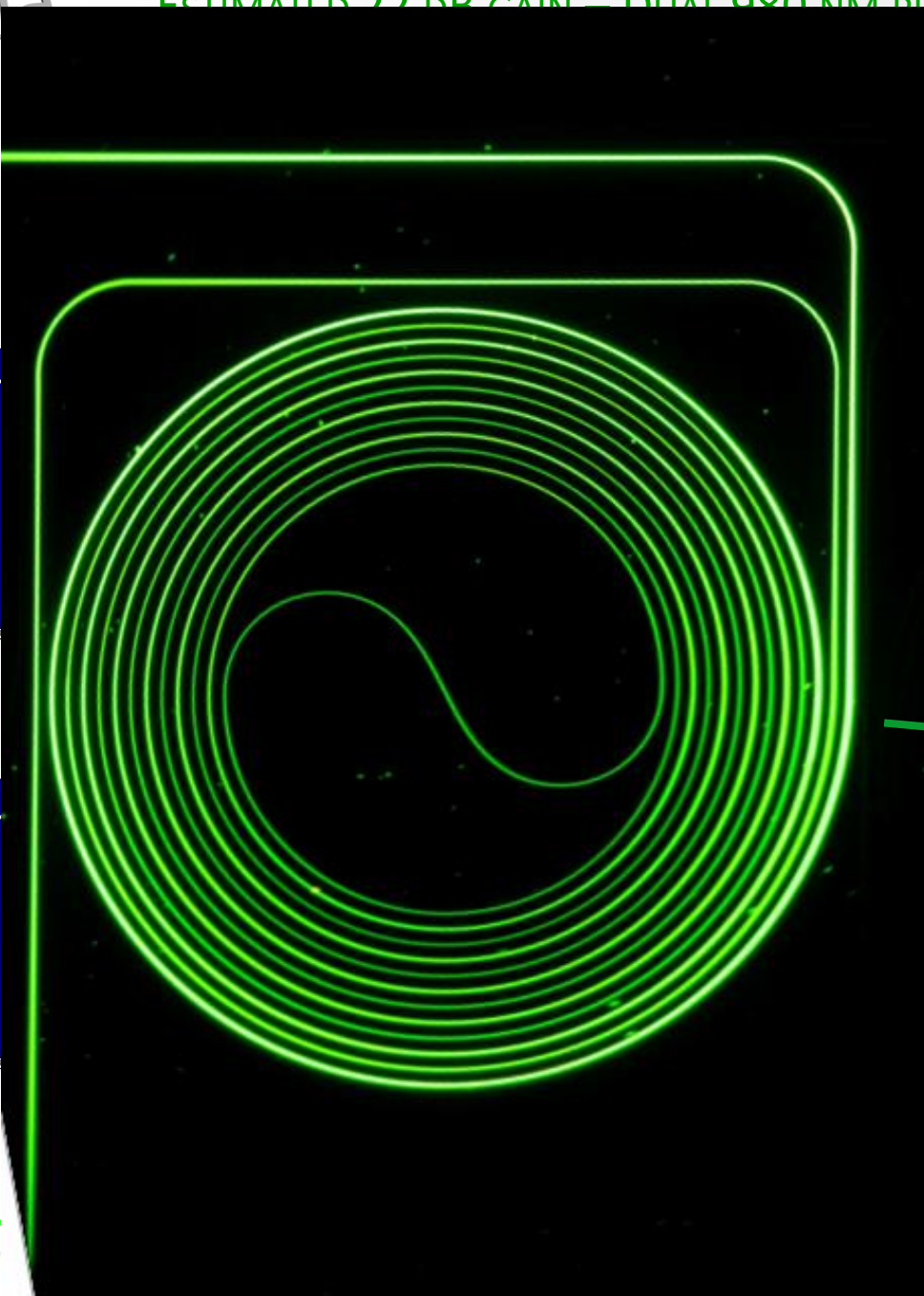
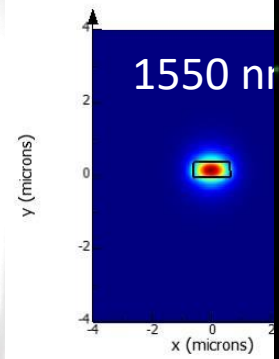
ING. Meindert Dijkstra
Support Staff at University of Twente





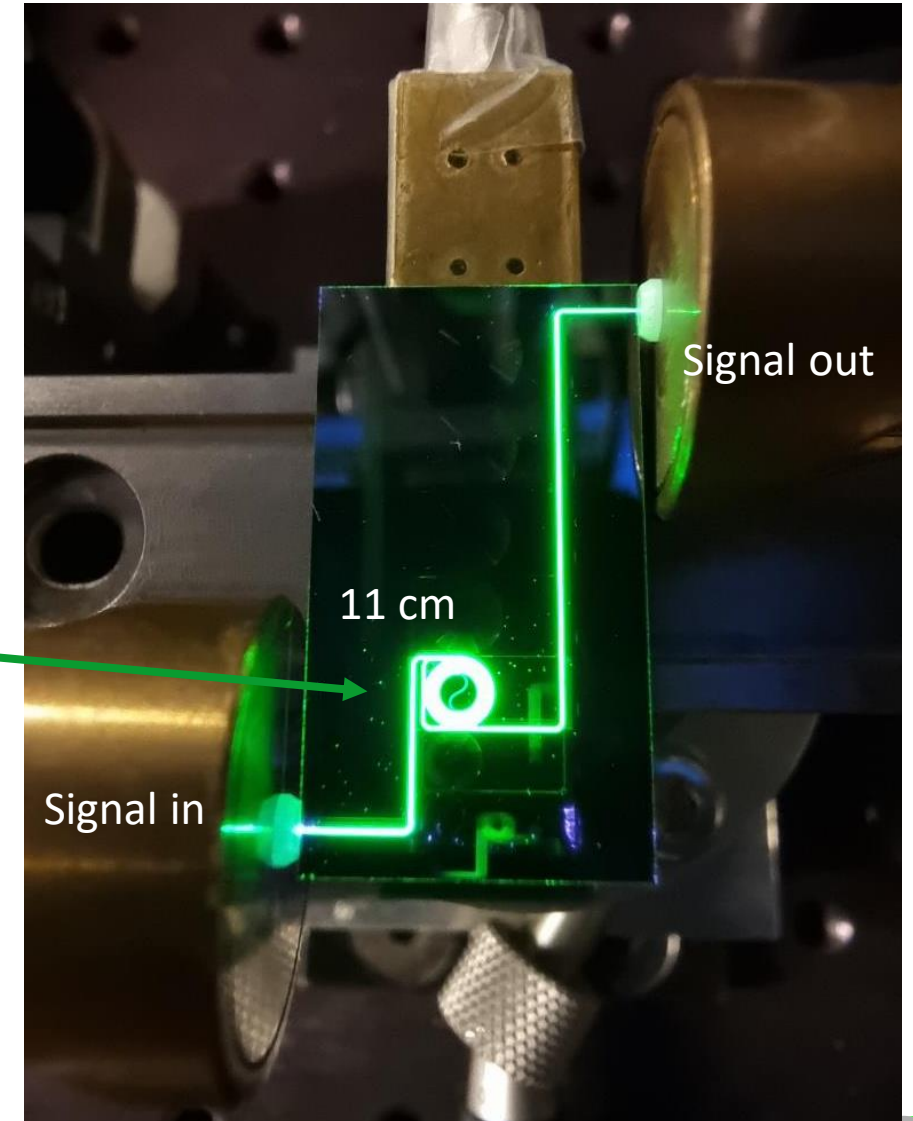


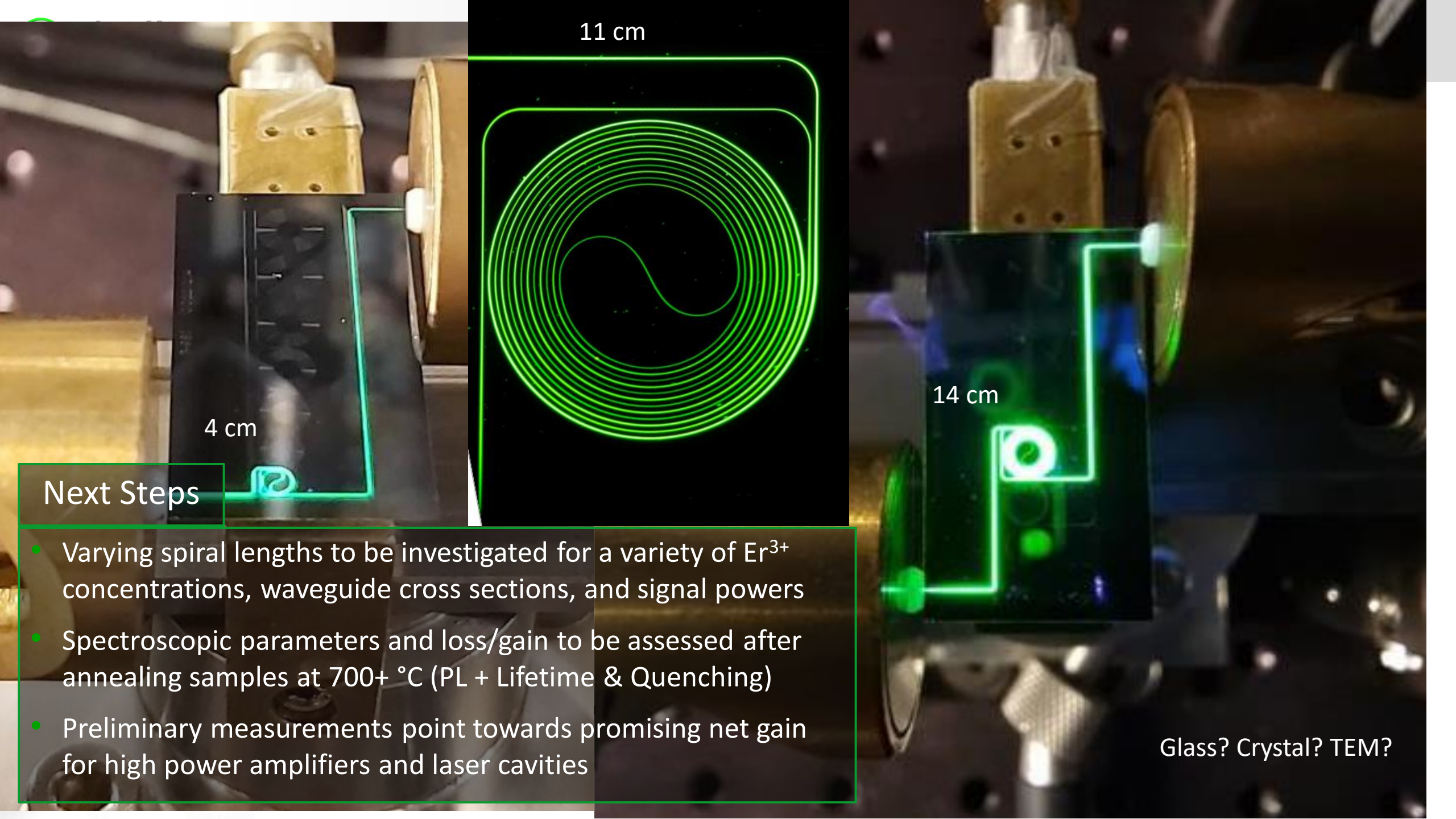
~1.2 x 0.4



600 nm

600





11 cm

4 cm

14 cm

Next Steps

- Varying spiral lengths to be investigated for a variety of Er^{3+} concentrations, waveguide cross sections, and signal powers
- Spectroscopic parameters and loss/gain to be assessed after annealing samples at $700+ \text{ }^\circ\text{C}$ (PL + Lifetime & Quenching)
- Preliminary measurements point towards promising net gain for high power amplifiers and laser cavities

Glass? Crystal? TEM?